HIGH-PERFORMANCE HF TRANSCEIVER YAESU FT-101ZD



GENERAL DESCRIPTION

The FT-101ZD is a precision engineered, highperformance HF transceiver of advanced design, providing all band (160 - 10 meters) operation on SSB, CW, and AM. This transceiver operates at an input power of 180 watts.

Advanced features include digital plus analog frequency display, continuously variable IF bandwidth (300 Hz - 2.4 kHz), a superb noise blanker with threshold adjustment, and an effective RF speech processor. The receiver boasts excellent dynamic range, despite its high sensitivity, for reliable operation in the presence of strong signals.

Built into every FT-101ZD are VOX, semi-break-in CW with sidetone, a 25 kHz crystal calibrator, selectable AGC, and a 10 dB/20 dB RF attenuator in the incoming signal path.

The FT-101ZD has been engineered for use. Controls and switches are laid out in an efficient and logical manner, so you won't have to fumble for a switch or knob when you need it quickly. And Yaesu designers have now made it possible for you to switch sidebands without recalibrating the display. All circuits, except the transmitter driver and final amplifier stages, are solid state. Solid state devices provide extremely high reliability and high component density, along with low power drain. The FT-101ZD may be operated from a variety of AC voltages, from 100 to 234 volts. A DC-DC converter, providing operation from a 13.5 VDC power source, is an available option.

For the economy FT-101Z, the counter unit is an available option, providing digital display capability should you want to upgrade your transceiver at a later date. Optional equipment on both models FT-101ZD and FT-101Z are the cooling fan, DC-DC converter, 600 Hz CW filter, and microphone.

A diecast front panel, and the heavy-duty case, provide maximum protection for your transceiver. If the ratings of this unit are not exceeded, it will provide the owner with many years of satisfying operation. Please read this manual carefully before commencing operation, in order to derive maximum satisfaction from your new YAESU transceiver.

SPECIFICATIONS

Frequency coverage:

•	v
160 m	1.8 - 2.0 MHz
80 m	3.5 - 4.0 MHz
40 m	7.0 - 7.5 MHz
30 m	10.0 - 10.5 MHz
20 m	14.0 - 14.5 MHz
17 m	18.0 - 18.5 MHz
15 m	21.0 - 21.5 MHz
12 m	24.5 - 25.0 MHz
10 m	28.0 - 29.9 MHz

Power requirements:

- AC 100/110/117/200/220/234 volts, 50/60 Hz DC 13.5 volts ± 10%
- (DC-DC converter optional)

Power consumption:

- AC 85 VA receive (73 VA HEATER OFF) 330 VA transmit DC 5.5 amps receive (1.1 amps HEATER OFF)
 - 21 amps transmit

Size:

345 (W) x 157 (H) x 326 (D) mm

Weight:

Approx. 15 kg.

TRANSMITTER

Emission type: LSB, USB, CW, AM

Power input: 180 watts DC (SSB, CW) 50 watts DC (AM) Carrier suppression: Better than 40 dB

```
Unwanted sideband suppression:
Better than 40 dB (14 MHz, 1 kHz)
```

Spurious radiation: Better than 40 dB down

Transmitter frequency response: 300 - 2700 Hz (-6 dB)

Third order distortion products: Better than 31 dB down Transmitter frequency stability: Less than 300 Hz after 10 minute warmup; less than 100 Hz after 30 minute warmup. Antenna output impedance: 50 - 75 ohms, unbalanced Microphone input impedance: 500 - 600 ohms (low impedance) RECEIVER Sensitivity: $0.25 \,\mu\text{V}$ for S/N 10 dB (SSB, CW) $0.5 \,\mu V$ for S/N 10 dB (AM) Image rejection: Better than 60 dB (160 - 12 m)Better than 50 dB (10 m) IF rejection: Better than 70 dB (160, 80, 20 - 10 m) Better than 60 dB (40 m, 30 m)Selectivity: SSB, AM 2.4 kHz at 6 dB down, 4.0 kHz at 60 dB down CW (with optional CW filter) 600 Hz at 6 dB down, 1.2 kHz at 60 dB down Bandwidth control: Continuous from 2.4 kHz to 300 Hz Audio output impedance: 4 - 16 ohms Audio output: 3 watts at 10% THD, 4 ohm load Specifications subject to change without notice.

Provided by http://www.yaesu-museum.com

Downloaded by Amateur Radio Directory

- 2 -

TUBES AND SEMICONDUCTORS

Vacuum Tubes		Integrated Circuits	(IC)	Zener Diodes	
12 BY 7 A	1	μ PA54H	1	WZ061	1
<u>6146B</u>	2	μPC7505H	1	WZ090	2
		μ PC78L12	1		
Transistors		μPC14308	1	Varactor Diodes	
T20A6	2	μPC2002H	1	182209	1
2SA495	1	MC3403P	1	1\$2236	1
2SA496Y	2	MC14024B	1	FC63	1
2SA564A	3	MSM9520RS	1		
2SA639	1	NJM78L05	1	Light Emitting Diodes	J
2SA733	1	SN76514N	1		9
2SA952LB	14	SN74LS123N	1		
2SB616	1	TA7060P	1	LED Display	
2SC372Y	15	TA7063P	1		6
2SC373	- 1				-
2SC380TMY	Y 15	Germanium Diodes			
2SC535A	1	1N60	11		
2SC732TM0	GR I ·	1S1007 (GB)	12		
2SC1000GR	2				
2SC1383	1	Silicon Diodes			
2SC1583	2	1\$1555	65		
2SC1674	1	10D1	7		
2SC1815GR	1	10D10	8		
2SC1815Y	6	V06B	2		
2SC2407	2	1SS53	25		
MPSA13	1	10000	20		
Field Effect Trans	sistors	Schottky Barrier Die	ode		
2SK19GR	8	ND487C2-3R	1		
25K19BL	1	(Ring Module)	•		
3SK40M	1	(=8)			
3SK51-03	7				
3SK73	1				
J310	2				
		D SERIES MODEL OUT			
		D SERIES MODEL CHA			
0	= BUILT-I	IN FEATURE X = AVAILABLE	OPTION	· · · · · · · · · · · · · · · · · · ·	

FEATURE	FT-101ZD	FT-101Z
ALL BAND CRYSTALS	0	0
COUNTER UNIT	0	X
DC-DC CONVERTER	X	x
CW FILTER	X	X
MICROPHONE	X	X
RF PROCESSOR	0	0
COOLING FAN	X	X

ļ

CONTROLS AND SWITCHES



(1) MODE

Selection of LSB, USB, CW-W (SSB filter), CW-N (optional CW filter) and AM is provided.

(2) WIDTH ON

When this button is pressed, the variable bandwidth function is activated.

(3) WIDTH

This control varies the IF bandwidth from 2.4 kHz down to 300 Hz. When the WIDTH switch is OFF, the bandwidth is fixed by the filter selected at the MODE switch.

(4) SELECT switches

When using the optional FV-901DM synthesized, scanning external VFO, these switches determine which component will control the transmit, receive, or transceive frequency.

- EXT..... This switch, when pressed, shifts control of the transceive frequency to the external VFO.
- TX EXT... This switch, when pressed, shifts control of the transmit frequency to the external VFO.
- RX EXT... This switch, when pressed, shifts control of the receive frequency to the external VFO.

- VFO..... This switch selects control of the transceive frequency on the FT-101ZD internal VFO.
- CH1, CH2. These switches select optional fixed channels, transceive only.

(5) PRESELECT

The preselector control peaks the RF and IF stages for the frequency in use.

(6) BAND

The bandswitch selects the frequency band in use: 160 - 10 meters.

(7) CLARIFIER

The clarifier control allows offset of ± 2.5 kHz from the frequency established by the main tuning dial.

(8) (9) CLARIFIER SELECT switches

Press the RX button for offset of the receive frequency.

Press the TX button for offset of the transmit frequency.

Press both buttons for offset of the transceive frequency.

(10) AF GAIN

The AF GAIN control varies the output level of the audio amplifier stages. Clockwise rotation increases the audio output level.

(11) RF GAIN

The RF GAIN control varies the gain of the RF and IF stages. Clockwise rotation increases the gain of these stages.

(12) LOADING

This control tunes the output circuit of the final amplifier pi network to match the feedpoint impedance of the load.

(13) PLATE

This control tunes the plate circuit of the final amplifier.

(14) MAIN TUNING KNOB

Rotation of this knob selects the operating frequency, in conjunction with the setting of the bandswitch. One revolution of the dial produces a frequency change of approximately 17 kHz.

(15) DIGITAL DISPLAY

The digital display reads out the operating frequency, with resolution to 100 Hz. The display unit is built into the FT-101ZD, and is an available option for the FT-101Z.

(16) ANALOG DIAL

The analog dial allows readout of the operating frequency to better than 1 kHz. The combination of the precision dial mechanism and drive unit provides zero backlash at slow tuning rates.

(17) **DIM**

This control allows dimming of the meter and dial lamps.

(18) **METER**

The meter displays final amplifier cathode current (IC), relative power output (PO), and ALC feedback voltage.

(19) NB

This control varies the threshold point for the noise blanker, and should be set to the minimum point that provides the desired blanking action.

(20) DELAY

This control sets the delay time for the VOX relay. For voice-actuated SSB, or semi-break-in CW, the operator may select the delay time most suitable for his or her operating habits.

(21) VOX GAIN

The threshold level for the VOX (voice operated relay) system can be varied using this control. In the PTT position, PTT (push to talk) control is provided, for relay control via the microphone PTT switch or footswitch.

(22) **DRIVE**

This control sets the carrier level for CW/AM and tuning purposes. When the RF processor is ON, this control varies the RF output on SSB, as well.

(23) MIC GAIN

This control sets the output level of the microphone amplifier stage. Clockwise rotation increases the mic gain level.

(24) COMP LEVEL

This control varies the compression level for the built-in RF speech processor. The processor does not function in the AM mode.

(25) FUNCTION switches

- PROC This switch activates the RF speech processor.
- ATT..... This switch allows the insertion of 10 or 20 dB attenuators in the incoming signal path.
- AGC S/F/OFF... This switch allows selection of the desired AGC decay time. In the OFF position, the AGC is switched off, and the S-meter will not function.
- PO/IC/ALC In the PO position, relative power output is displayed on the meter. In the IC position, final amplifier cathode current is displayed. In the ALC position, ALC voltage is displayed. Regardless of the setting of the meter switch, the meter functions as an S-meter on receive.
- NB/MARK..... In the NB position, the noise blanker is activated. In the MARK position, the internal crystal calibrator is activated.

(26) POWER

This is the main ON/OFF switch for the transceiver.

(27) HEATER

With the HEATER switch on, heater voltage is applied to the driver and final amplifier tubes. This switch may be turned off during periods of RX, when energy conservation is critical.

(28) PHONES

This is a standard '4" phone jack for use with headphones.

(29) MIC

This is a 4 conductor jack for microphone and PTT input.









Headphone and external speaker plug





- 6 -

REAR APRON



(1) **RF OUT**

RF output of 3 volts RMS is available at this jack for use with a transverter. Output is from the driver stage.

TONE OUT (7)

The CW sidetone may be fed to an external receiver through this jack.

(8) A TRIP IN

(2) GND

For best transceiver performance, as well as protection from electrical shock, a good ground connection should be made at this point, using a heavy, braided wire of the shortest length possible.

3) ANT

Standard "UHF" connector for the antenna.

(4) RCV ANT

This jack is switched in parallel with the ANT jack on receive, for use with an external receiver.

(5) PO ADJ

This control adjusts the relative power output meter.

(6) ACC

Transceiver operating voltages and relay connections can be accessed through the accessory jack. Please insert the ACC plug at all times, to provide heater voltage for the driver and final amplifier tubes.

Anti-trip input from an external receiver may be made via this jack, to prevent the receiver audio output from tripping the FT-101ZD VOX.

(9) KEY

The CW key may be connected at this point. Keyup voltage is 7 volts, and key-down current is 1.5 mA. Be sure your electronic keyer's output switch will handle these levels.

(10) EXT VFO

Connection of an external VFO, such as the FV-101Z or FV-901DM, can be made at this jack.

(11) FUSE

This is the fuse holder. For 100 - 117 volts, replace with only a 5 amp use. For 200 - 234 volts, use a 3 amp fuse. Replace fuses only with a fuse of the proper rating.

(12) IF OUT

Wideband IF output is available at this jack for use with a spectrum analyzer, etc.

(13) **POWER**

Connect the AC power cord at this point, being certain that your AC supply voltage matches the voltage specification for your transceiver. See the transformer primary connection chart. When using the optional DC-DC converter, the DC supply is connected at this point. DO NOT CONNECT THE AC POWER CORD TO A DC POWER SOURCE. OUR WARRANTY DOES NOT COVER DAMAGE CAUSED BY SUCH IMPROPER POWER CON-NECTIONS.

(14) **TONE**

This control varies the CW sidetone output level.

٦

(15) A TRIP

This control varies the level of the VOX anti-trip circuit.

(16) PTT

External control of the transceiver PTT (push to talk) system may be made at this jack, for use with a footswitch, etc.

(17) PATCH

Microphone or phone patch input may be made at this jack. Impedance is 500 ohms.

(18) EXT SP

This is a miniature phone jack for speaker output. When a plug is inserted into this jack, the transceiver internal speaker will be cut off. Impedance is 4 - 16 ohms.

(19) DC-DC CONVERTER (OPTION)

The optional DC-DC converter allows operation from a 13.5 volt DC power source.

(20) COOLING FAN (OPTION)

The optional cooling fan keeps the tubes at a safe operating temperature, when they are used in a hot environment. The 2 pin fan power jack supplies 100 volts to the fan.

ACCESSORIES

The following accessories are included with your new transceiver:

(1) AC POWER CORD

The power cord comes equipped with a 6-prong connector for connection to the AC supply.

1 .

ľ

(2) ACC PLUG

The accessory plug allows access to relay contacts and transceiver operating voltages. The ACC plug must be inserted in the accessory socket for proper operation of the transceiver, whether or not external connections are being made.

(3) PHONO PLUG 2

Use these plugs for interface with station equipment via the FT-101ZD rear panel.

(4) SPARE FUSES 5A (3A) 1 each

When replacing fuses, be absolutely certain to use a fuse of the proper rating. OUR WARRANTY DOES NOT COVER DAMAGE CAUSED BY IMPROPER FUSE REPLACEMENT. For 100 -117 volt AC operation, use a 5 amp fuse. For 200 - 234 volt operation, use a 3 amp fuse.

INTERCONNECTIONS





FT-101ZD/FTV-901R

INSTALLATION

The FT-101ZD is designed to be a single-unit station for fixed or portable operation from AC power. Power supply connections providing for operation from a variety of source voltages are available. Please read the following sections carefully, so as to ensure proper installation of your new transceiver.

PRELIMINARY INSPECTION

Upon opening the packing carton, immediately give the transceiver a thorough visual inspection. Check to see that all controls and switches are working freely, and inspect the cabinet for any signs of damage. If any damage has been sustained, immediately contact the shipping company, and document the damage completely. Save the packing carton and foam packing material for possible use at a later date.

BASE STATION INSTALLATION

The FT-101ZD is designed for use in many areas of the world, using supply voltages that may differ from your local supply voltage. For this reason, be absolutely certain that the voltage specification marked on the rear of the transceiver agrees with the local AC supply voltage. THIS INSPECTION MUST BE MADE BEFORE CONNECTING THE AC POWER CORD TO THE REAR APRON OF THE TRANSCEIVER.

CAUTION

PERMANENT DAMAGE WILL RESULT IF IM-PROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER. OUR WARRANTY DOES NOT COVER DAMAGE CAUSED BY APPLICATION OF IMPROPER SUPPLY VOLT-AGE. DO NOT CONNECT THE AC POWER CORD TO A DC POWER SOURCE.



The transceiver should be connected to a good earth ground. The ground lead should be made of a heavy, braided wire, and should be connected to the GND terminal on the rear apron of the transceiver.

MOBILE INSTALLATION

(Note: The DC-DC converter described herein is optional equipment. See your Yaesu dealer.)

When the optional DC-DC converter is installed, the FT-101ZD will operate satisfactorily from a 13.5 volt DC power source capable of providing the required current. The DC power cord is included with the DC-DC converter kit.

For under-dash mobile mounting, a special mobile mounting bracket is an available option for your transceiver. The FT-101ZD should be located away from heater ducts, and a minimum of two inches of air space on all sides is recommended, to allow proper air flow around the cabinet. Never stack other units above or below the FT-101ZD, as the accumulated heat from both units could cause damage.

The transceiver requires an average of 14 amps on transmit, with 20 amps on voice peaks. The DC power cable comes equipped with a 20 amp fuse. Be certain to use only a 20 amp fuse when making replacement.

When making battery connections, be absolutely certain that the RED lead is connected to the POSITIVE battery terminal, and the BLACK lead connected to the NEGATIVE battery terminal. Reverses connections could cause permanent damage to the use co

It is recommended that the power connections be made directly to the battery, instead of to the ignition switch, etc. The battery provides considerable filtering action against ignition noise, and connection to the ignition switch can place the power line in a noisy circuit. Keep the power lead as short as possible, and keep the lead away from ignition cables. Before connecting the DC power cable to the transceiver, check the battery voltage with the engine running (battery charging). If the voltage exceeds 15 volts DC, the vehicle voltage regulator should be adjusted, so as to limit the highest charging rate to less than 15 volts. As well, do not operate the transceiver if the DC supply voltage is less than 12 volts. The transceiver should always be turned off when the car is started, to prevent voltage transients from damaging the power supply components.

ANTENNA CONSIDERATIONS

The FT-101ZD is designed for use with an antenna system presenting a 50 - 75 ohm resistive load at the antenna jack. While the transmitter output circuitry is designed for uniform response within this impedance range, significant departures from the 50 - 75 ohm specification will result in seriously degraded transceiver performance, and may result in damage to the final amplifier tubes.

If an open-wire feedline is used, or if the input impedance of the antenna system presents a higher or lower impedance than specified, some sort of antenna tuner must be used to provide the proper impedance for the transceiver. See your Yaesu dealer for details of the FC-902 antenna coupler.

For mobile operation, most of the commerciallyavailable antennas will provide satisfactory results, if care is taken to tune the antenna for minimum SWR. The outer conductor of the coaxial cable should be securely grounded to the automobile chassis at the antenna mount. See your Yaesu dealer for details on the RSL series of mobile antennas. The tuning procedure for this transceiver is not complicated. However, care should be exercised when tuning so that peak performance of the equipment is secured. The following paragraphs describe the procedure for receiver and transmitter tuning.

INITIAL CHECK

Before connecting the transceiver to the power source, be certain that the voltage specification marked on the rear of the transceiver matches your local supply voltage, and also confirm that a fuse of the proper rating is being used.

FREQUENCY SELECTION

Frequency readout on the FT-101ZD is by digital as well as analog displays. The FT-101Z uses analog display only. The analog readout dial provides resolution to 1 kHz, while the FT-101ZD digital display provides resolution to 100 Hz. The digital display may be added to the FT-101Z as an option. See your Yaesu dealer for details.

RECEIVE OPERATION

- (1) Preset the controls and switches as follows: POWER OFF IIEATER ... OFF VFO..... Switch pushed VOX GAIN .. PTT position RF GAIN ... Fully clockwise AF GAIN ... Adjust later for comfortable level
 BAND Desired band MODE Desired mode
 PRESELECT . Desired mode
 PRESELECT . Desired band segment
 AGC OFF
 ATT OFF
 MARK/NB ... OFF
- (2) Turn the power switch to ON. The meter will light up, and the operating frequency will be displayed on the dial window (FT-101ZD). Adjust the AF GAIN control for a comfortable listening level, and adjust the PRE-SELECT control for maximum receiver noise or signal level. The PRESELECT control may require repeaking as the transceiver is tuned across the band.

- (3) The RX CLARIFIER may be utilized if the received signal is drifting. Push the RX button, and rotate the CLARIFIER control for offset of up to 2.5 kHz. A red LED indicator will light up when the clarifier is in use.
- (4) When pulse-type noise is encountered, the NB (Noise Blanker) switch should be activated. Advance the noise blanker level control (located on the front panel) to the point which provides the desired blanking. Do not advance the level control beyond the point required to eliminate the noise pulses.
- (5) For varying the width of the IF passband, press the WIDTH button, and rotate the WIDTH control. In the IF, two 8-pole crystal filters are used. One filter is fixed, and presents a boundary for the bandwidth. The center frequency is then varied across the passband of the second filter, using a mixing scheme that provides no change of pitch in the received signal.

The result is continuously variable bandwidth, from 2.4 kHz down to approximately 300 Hz. When the WIDTH switch is turned OFF, the second IF filter is instantly aligned with the first filter, returning the receiver to a 2.4 kHz bandwidth.

(6) For extremely strong signals, the ATT (attenuator) switch may be activated, providing 10 dB or 20 dB of attenuation on the incoming signal path, depending on the position of the ATT switch.

TRANSMITTER TUNING

The following tuning procedure must be performed prior to commencing operation on the desired mode. See the paragraphs relating to the specific mode after basic transmitter tune-up has been accomplished.

Be certain that a dummy load or matched antenna is connected to the antenna receptacle on the rear apron of the transceiver. It is possible to damage the final amplifier components of this equipment if this simple precaution is not followed prior to commencing transmission. Do not exceed 10 seconds of key-down time while tuning.

As well, be certain that the ACC plug is inserted into the rear apron ACC jack. Without this plug, there will be no power applied to the tube heaters. Heater voltage is applied through pins 1 and 2 of the accessory socket.

(1)	Preset the controls and switches as follows:
	MODE TUNE
	DRIVE Fully counterclockwise
	DELAY Fully counterclockwise
	MIC GAIN Fully counterclockwise
	COMP LEVEL Fully counterclockwise
	HEATER ON
	PROC OFF
	PO/IC/ALC IC
J	PLATE
	ment
	LOADING 0
	PRESELECT Peaked on receive for *
	maximum response
	TX CLARIFIER OFF (button not pushed)

- (2) Turn the HEATER switch ON, and wait 1 minute for the tube heaters to warm up.
- (3) Set the VOX GAIN switch to the MOX position. Observe the reading on the IC meter: it should read 50 mA with no drive applied. If it is not, adjust the PB-1968 BIAS control for a resting current of 50 mA on the IC meter. Refer to the BIAS Adjustment on Page 37. Be certain that the DRIVE control is fully counterclockwise for this adjustment.
- (4) Set the VOX GAIN switch to MOX. Advance the DRIVE control for a reading of 150 mA.
- (5) Peak the PRESELECT control for a maximum meter reading. If the meter reading exceeds 150 mA, reduce the setting of the DRIVE control.
- (6) Rotate the PLATE control for a minimum reading ("dip") on the IC meter. Return the transceiver to the receive mode by rotating the VOX GAIN switch out of the MOX position.

LOADING POSITIONS

BAND	FREQUENCY	POSITION
100-	1.8MHz	2.5
160 m	2.0MHz	6.0
	3.5MHz	3.0
80 m	4.0MHz	6.0
40	7.0MHz	6.0
40m	7.5MHz	6.5
	10.0MHz	7.0
30 m	10.5MHz	8.0
AA	14.0MHz	3.0
20 m	14.5MHz	4.0
17_	18.0MHz	2.0
17 m	18.5MHz	2.0
18	21.0MHz	2.0
15 m	21.5MHz	2.5
10	24.5MHz	3.0
12 m	25.0MHz	3.0
10m A	28.0MHz	2.0
10m B	28.5MHz	2.0
10m C	29.0MHz	2.0
10m D	29.5MHz	2.0

NOTE: LOADING positions are nominal. Minor variations from positions shown are to be expected.

FINAL TUNING

Final transmitter tuning uses the relative power output setting of the METER switch. At full rated output, using a 50 ohm load, the PO meter will indicate between 1/2 and 2/3 of full scale deflection. If the PO reading is too high (off scale) or too low (1/4 scale or less), and if the load impedance is very close to 50 ohms, the PO ADJ control on the rear apron may be varied to provide the proper deflection. Once the PO meter is calibrated, off-scale deflections are the result of reflected power (high SWR), and corrective action may be required in the antenna system.

Set the controls as follows for final tuning:

- (1) Set the METER switch to PO. Rotate the DRIVE control to the 9 o'clock position.
- (2) Rotate the VOX GAIN control to the MOX position, and rotate the PRESELECT control for a maximum meter reading.
- (3) Rotate the LOADING control for a maximum meter reading. Rotate the PLATE control for a maximum meter reading.
- (4) Again rotate the LOADING control and PLATE control, each time advancing the

- 13 -

DRIVE control approximately 2 steps, until the DRIVE control is fully clockwise. The transmitter is now tuned for maximum power output. Do not exceed the maximum tuning time stipulated previously. Return the VOX GAIN switch to the VOX position (out of the MOX position). return the METER switch to IC, and return the DRIVE control to the fully counterclockwise position.

SSB OPERATION

t

After completing the above tuning procedure, set the MODE switch to USB or LSB as desired. Set the VOX GAIN control to PTT, and activate the transmitter by pushing the microphone PTT switch or the footswitch, if used. With the METER switch set to the ALC position, speak into the microphone in a normal voice. Advance the MIC GAIN control until the meter kicks up to the midscale of the green-colored portion of the meter scale.

Note: When the METER switch is set to IC, voice modulation peaks will indicate 150 - 200 mA. Actual peak current, though, is approximately 2 times the indicated value.

To set the sensitivity of the VOX (voice-operated T/R switching) system, advance the VOX GAIN control slowly while speaking into the microphone. Advance the VOX GAIN control to the point where the speech signal activates the transmitter.

Set the antitrip potentiometer on the rear apron to the minimum point which prevents the speaker output from tripping the VOX. Do not use more VOX gain nor antitrip than is necessary. Adjust the front panel DELAY control for the desired relay recovery time.

RF SPEECH PROCESSOR ADJUSTMENT

The FT-101ZD RF speech processor, when correctly adjusted, will improve the intelligibility threshold at the receiving end, by increasing the average SSB power output. RF clipping is applied to the IF signal, which is then filtered to remove harmonics and out of band intermodulation products. RF envelope clipping causes much less distortion than that caused by an equivalent amount of AF clipping, and the result is an output signal with more "punch". Set the PROC switch to OFF, and set the MIC GAIN control as described previously (voice peaks falling within the green zone of the ALC meter scale). Now set the PROC switch to ON, and set the COMP LEVEL control to the 10 o'clock position. Advance the DRIVE control so that the desired power output is obtained, and be sure that the ALC meter indication is within the green zone.

With the RF speech processor activated, the ALC meter indication may not be quite as high as when the processor is off. This is entirely normal, because the average power output is higher with the processor, although the peaks are being clipped.

Setting the COMP LEVEL control up to the 3 o'clock position will provide up to 10 dB of compression. Advancing the control beyond the 10 o'clock point may, however, degrade the voice-to-noise ratio, so caution is recommended.

CW OPERATION

After completing the tuning procedure, insert the key line into the KEY jack on the rear panel.

The operator may select any power output desired by advancing the DRIVE control. Once the maximum power output level has been reached, the DRIVE control should not be advanced further.

The transmitter may be activated by the VOX circuit, or by the PTT or MOX systems. The TONE control on the rear apron of the transceiver sets the CW sidetone level.

The key-up voltage at the key jack is 7 volts, and the key-down current is 1.5 mA.

For receiving, two positions of selectivity are provided. When the optional CW filter is installed, the operator may select between the 600 Hz bandwidth of the CW filter and the 2.4 kHz bandwidth of the SSB filter. The WIDTH control may be used with either position of the MODE switch: CW-W or CW-N.

AM OPERATION

AM operation of the transmitter is accomplished by setting the MODE switch to the AM position and inserting the proper amount of carrier with the DRIVE control.

After completing basic transmitter tune-up, place the MODE switch in the AM position. Activate the transmitter, and rotate the DRIVE control until the meter reads .10 (100 mA) in the IC position of the METER switch. While speaking into the microphone in a normal voice, increase the MIC GAIN control until the meter indicates very slight movement with voice peaks. Care must be exercised that the DRIVE control is not advanced too far. Do not exceed .10 (100 mA) meter indication during AM operation or damage to the transmitter final amplifier tubes may result.

SELECT SWITCHES,

The SELECT switches allow selection of internal or external VFO frequency control, as well as selection of up to 2 optional crystal-controlled channels.

When the crystal-controlled channels are installed, they may be selected by pressing CH1 or CH2, as desired. See the crystal information elsewhere for full information on crystal requirements.

The external VFO, FV-101Z and FV-901DM, which provide versatile operations with your FT-101ZD, are available from your Yaesu dealer.

Because there is no calibrated dial for the FV--901DM, it can't be used with the analog FT -101Z.

For transceive frequency control on the external VFO, press EXT. For external VFO control of the transmit frequency, with receive frequency control on the FT-101ZD, press TX EXT. For receive frequency control on the external VFO, and transmit frequency control on the FT-101ZD, press RX EXT. For full transceive control on the FT-101ZD, press VFO.

DIAL CALIBRATION AND FREQUENCY DETERMINATION

The FT-101ZD mixing scheme accounts for the difference in carrier frequencies between USB and LSB. For this reason, no recalibration is required. Once the calibration is properly aligned (at the factory, or in shop), no further adjustment is required for accurate frequency derivation. The 25 kHz calibrator is included largely for alignment purposes, as it provides a useful reference signal for signal peaking, etc.

Frequency readout on the FT-101ZD digital display is straightforward. The full operating frequency is displayed, with resolution to 100 Hz.

The analog display on the FT-101Z and FT-101ZD transceivers provides easy determination of the operating frequency. The frequency displayed on the analog sub dial (and the main display window, for the FT-101Z) is added to the lower band edge frequency.

For example, if the analog dial indicates 074, as shown in the example, and the BAND switch is on 40 meters (lower band edge: 700C kHz), the operating frequency will be 7074 kHz. By rotating the BAND switch, this position of the analog display will produce 14074 kHz for 20 meters, 21074 for 15 meters, etc. For 80 and 12 meters, the lower band edges are 3500 kHz and 24500 kHz, while for 160 meters the band edge is 1.5 MHz. Therefore, the dial should read 074 to produce 3574 kHz, but 374 for 1874 kHz. Be careful so as not to operate outside the amateur bands.



FIXED CHANNEL CRYSTAL INFORMATION

Two fixed channels may be used with your FT-101ZD, using optional crystals. Crystals are available from your Yaesu dealer. Crystals must meet the specifications shown in Table 2, and must fall within the operating range 5500 - 5000 kHz. Frequency calculation is made from the formula

 $\mathbf{F}_{\mathbf{X}} = \mathbf{F}_{\mathbf{1}} - \mathbf{F}_{\mathbf{0}}$

where F_x is the crystal frequency F_1 is a constant derived from Table 1 F_0 is the operating frequency.

For example, let us say it is desired to operate on 7199 kHz LSB. Referring to Table 1, we see that for 40 meter LSB, F_1 is 12501.5 kHz. Subtracting F_0 (7199 kHz) from F_1 (12501.5 kHz) yields 5302.5 kHz, the crystal frequency (F_x).

For operation on 21420 kHz USB, compute the crystal frequency as follows:

 $F_x = 26498.5 - 21420 = 5078.5 \text{ kHz}.$

Inspection of the values of F_1 in Table 1 will reveal that the 7199 kHz crystal for LSB will work on 14199 kHz, 21199 kHz, etc. Of course, LSB is not normally used on these bands. If the operator switches to USB, the operating frequency will be moved 3 kHz (in this case, to 14196 kHz, 21196 kHz, etc.). If the move is made from LSB to CW, the frequency will move 2.3 kHz down.

MODE	USB	LSB	c w
160m	699 8.5	7001.5	6999.2
80m :	8998.5	9001.5	8999.2
40m	12498.5	12501.5	12499.2
30 m	15498.5	15501.5	15499.2
20m	19498.5	19501.5	19499.2
17m	23498.5	23501.5	23499.2
15 m	26498.5	26501.5	26499.2
12 m	29998.5	30001.5	29999.2
10m A	33498.5	33501.5	33499.2
10m B	33998.5	34001.5	33999.2
10m C	34498.5	34501.5	34499.2
10m D	34998.5	35001.5	34999.2

Table 1

Туре	HC-25/U	
Load Capacitance	30pF	
Series Resistance	25 Ohms or less	
Static Capacitance	7pF or less	
Drive Level	5mW	

Table 2

CW FILTER INSTALLATION (OPTION)

- (1) Remove the top cover of the transceiver case, as shown in Fig. 1.
- (2) Refer to Fig. 2, and locate the NB-FIX circuit board. Remove its mounting screws, because this board is obstructing the removal of the IF unit.
- (3) Remove the 12-pin, 13-pin, and 15-pin plugs from their sockets on the IF unit. Remove the IF unit mounting screws, and remove the IF unit from the transceiver case.



Figure 1



Figure 3

- (4) Install the optional CW filter as shown in the foil side view of the IF unit (Fig. 3). Make the fastening nuts snug, and solder the pins of the filter to the circuit board, and remove the 2 jumper wires shown in Figure 3.
- (5) Re-install the IF unit, being careful to connect the 12-pin, 13-pin, and 15-pin plugs in the correct sockets. Refer to Fig. 2 to be sure. Re-install the NB-FIX unit, and replace the top cover of the transceiver.
- (6) When the optional CW filter is installed, the CW-N position of the mode switch will activate this filter. In the CW-W position, the SSB 2.4 kHz filter will be in use. The WIDTH control is usable in all modes.



Figure 2



Figure 4

DC-DC CONVERTER INSTALLATION (OPTION)

The optional DC-DC converter is easy to install in a matter of minutes. Please follow the instructions carefully, in order to make the proper connections.

- (1) Install the DC-DC converter module as shown in the drawing. Use the four screws supplied with the kit. Do not force the plug into the socket, as the connection should be smooth, yet solid.
- (2) Check the DC cable fuse socket, located in the positive (red) lead, to be certain that a 20 amp fuse is installed.
- (3) When making connections to the battery, be absolutely certain that the proper polarity is observed. The RED lead should be connected to the POSITIVE (+) battery terminal, and the BLACK lead should be connected to the NEGATIVE (-) terminal. OUR WARRANTY DOES NOT COVER DAMAGE CAUSED BY REVERSED POLARITY CONNECTIONS.
- (4) Before connecting the DC power cable to the transceiver, check the automobile voltage regulator level with the engine running (battery charging). The maximum charging rate

should be 15 volts or iess. If the voltage is higher than this level, please adjust the voltage regulator for a maximum of 15 volts. This precaution applies, as well, to bench power supplies, which should be adjusted in the same fashion. Also, the transceiver should not be operated from a supply voltage of less than 12 volts.

(5) Connect the DC cable to the transceiver. Power connections are made automatically when the DC cable is connected to the POWER jack.

NOTES ON MOBILE INSTALLATION

Be certain that sufficient room is provided for free air circulation around the transceiver. If the transceiver must be placed on the car seat, set it on a board or other rigid object, in order to provide the necessary air circulation (and to avoid possible heat damage to the uphoulstery.

A special mobile mounting bracket is available from your YAESU dealer.

The DC supply should be capable of providing 20 amps on voice peaks, 14 amps continuous. The HEATER switch may be turned off during long periods of reception, for energy conservation.



COOLING FAN INSTALLATION (OPTION)

The FT-101ZD cooling fan may be used with other models of Yaesu equipment. Installation is easily accomplished in minutes.

Hold the fan up to the rear panel in its proper location. Determine the proper length of the twowire power lead to the motor. Solder the leads to the 2-pin plug supplied with the fan. The 4-pin plug is not needed for FT-101ZD installation.

Install the fan onto the rear panel of the transceiver, as shown in the drawing. Insert the power lead from the fan into the fan socket on the rear panel.

ŝ



٩





COUNTER UNIT INSTALLATION ON FT-101Z

This section will deal with the installation of the COUNTER UNIT and digital display, which are optional equipment for the economy FT-101Z model.

PARTS NEEDED(1)Optical Filter with double-face tape(1)Counter Module(1)Guide Pins(2)Support Tower(1)Vinyl Tubes(2)

- (1) Remove the top cover of the transceiver, according to the drawing on page 17.
- (2) Remove the screws marked "A" in Figure 1. These screws support the LED board.
- (3) Remove the screws marked "B" in Figure 1, as well as the tension spring, and remove the analog display panel.
- (4) Locate the analog display lamp. Cut the leads to this lamp, insert 1 lead each into the vinyl tube supplied with the counter kit, and position these leads out of the way of the VFO gears, etc.
- (5) Install the orange optical filter on the inside of the front panel of the transceiver, in the position formerly occupied by the analog display panel. Be sure that it is correctly centered. The filter is held in place by the double-face tape included with the filter.
- (6) Install the two guide pins into the holes previously occupied by the "A" screws. When doing this, install the LED board in its previous position. Install the support tower into the hole marked "C" in Figure 1.
- (7) Remove the 820 ohm (Gray-Red-Brown) resistor from the terminal strip marked "E" in Figures 1 and 2.

14

(8) Install the COUNTER UNIT. The connection to the guide pins should not be forced. Use the screws previously installed at "A" for securing the counter module at points "C" (support) and "D" in Figure 1. Connect the COUNTER UNIT 9-pin plug into the 9-pin. socket on the transceiver at point "G" in the drawing. The coaxial cable from the COUNTER UNIT is connected to point "F" in Figure 1.

(9) Close the transceiver. No alignment of the unit is necessary, unless some change in the preset carrier frequencies is required for a special application. In this case, refer to the section on the COUNTER UNIT in the "ALIGNMENT" chapter of this manual.



Figure 3

Provided by http://www.yaesu-museum.com

Downloaded by

Amateur Radio Directory



- 21 -

CIRCUIT DESCRIPTION

The block diagram and following circuit description will provide you with a better understanding of the design of this transceiver. The circuit description is tailored to the full-feature FT-101ZD, and the reader should note that the counter unit and digital display are optional features for the FT-101Z.

The FT-101ZD consists of a premix-type single conversion system, using a 9 MHz IF for all modes of operation.

RECEIVER

The RF input signal from the antenna is fed through antenna relay RL_2 , lamp fuse FH_2 , attenuator switch S_{2004} (located on the LEVER SW unit, PB-1975), 9 MHz trap L_{2101} and C_{1207} (located on the TRIMMER A UNIT), and input transformer T_1 to pin 3 of the RF UNIT.

RF UNIT (PB-2154)

The incoming signal is amplified by the RF amplifier, Q_{101} (3SK51-03), a dual-gate MOS FET with excellent rejection of cross modulation and intermodulation. The amplified signal is fed to the Schottky barrier diode module, Q_{102} (ND487C2-3R), where the RF signal is mixed with a local signal delivered from Q_{104} (2SC2407), resulting in a first IF of 8.9875 MHz. The IF signal is then amplified by Q_{103} (J310) and fed to J₁₀₁.

IF UNIT (PB-1963)

The IF signal at pin 9 of J_{403} is amplified by Q_{408} (J310) and passed through a monolithic filter, XF₄₀₄, which has a ±10 kHz bandwidth. The monolythic filter provides early protection from IMD, while providing a wide-bandwidth point for noise blanking. The IF signal is then fed to noise blanker gate D_{404} (1S1007), which functions as an ON/OFF switch controlled by noise blanker driver Q_{411} (MPSA13).



The IF signal is then passed through the SSB filter XF_{401} (or optional CW filter XF_{402}). Selection of the filter to be used is made by diodes $D_{405} - D_{408}$ (1S1007), depending on the mode of operation.

The IF signal is then fed to the IF first mixer, Q_{412} (3SK51-03), where the incoming signal is heterodyned with a 19.7475 MHz $\pm \Delta f$ local signal delivered from crystal oscillator Q_{421} (2SC535A) and buffer amplifier Q_{423} (2SC372Y), resulting in a signal of 10.76 MHz $\pm \Delta f$.

The new 10.76 MHz $\pm \Delta f$ signal is fed through filter XF₄₀₅ to the IF second mixer, Q₄₁₃/Q₄₁₄ (2SK19GR), where the filtered signal is heterodyned with the 19.7475 MHz $\pm \Delta f$ signal delivered from Q₄₂₂ (2SC372Y), resulting in an 8.9875 MHz IF signal, the same as the original IF.

This process varies the IF signal across the passband of the second IF filter. The combination of the two filters, XF_{401} and XF_{405} , provides continuously variable width of the IF passband. The frequency of crystal oscillator Q_{421} is varied by varactor diode D_{418} (1S2209).

The output from the IF second mixer is fed to a two-stage IF amplifier, consisting of Q_{415} and Q_{416} (3SK51-03), and delivered through diode switch D_{401} (1S1555) to the AF UNIT.

A portion of the output from Q_{416} is rectified by D_{416} and D_{417} (1N60) to produce AGC voltage. Q_{417} (2SC372Y) provides the necessary buffering between the IF and AGC circuits. The AGC voltage is amplified by Q_{418} (2SC372Y), and applied to gate 2 of the RF and IF amplifiers, to control the gain of these stages. The AGC voltage is also amplified by Q_{419} (2SK19GR) for S-meter indication.

For use with the FV-101Z or FV-901DM scanning VFO, or other optional equipment, the AGC voltage is fed through buffer Q_{425} (**2SK19GR**) and fed to the AGC OUT terminal on the EXT VFO jack, located on the rear panel.

On AM, the output signal from Q_{416} is amplified by Q_{2408} (2SC380Y) and passed to the AM detector, D_{2406} (1N60). The resulting audio signal is amplified by Q_{2409} (2SC1815Y) and delivered to the final audio stage.





Width Control Action





NB-FIX UNIT (PB-1961)

A portion of the 8.9 MHz IF signal is fed through buffer Q_{410} (2SC372Y) and amplified by Q_{206} and Q_{205} (2SC1583).

When a carrier of noise-free modulated signal is received, the IF signal is rectified by D_{201} and D_{202} (1N60), producing a DC voltage. This DC voltage is amplified by Q_{202} (2SC372Y), which charges C_{214} , for AGC purposes. The AGC voltage is used to control the gain of Q_{206} and Q_{205} .

When impulse-type noise is received, D_{203} and D_{204} (1N60) rectify the IF signal, producing a DC voltage which controls the NB switch Q_{411} (2SC372Y).

Noise pulses have a very short duration, but high amplitude. Because of the very slow time constant of the C_{214}/R_{212} discharge path, AGC voltage is not induced by these short-duration pulses. Therefore, Q_{206} and Q_{205} operate at full gain, providing maximum voltage to the base of Q_{411} . When a pulse is received, Q_{411} biases D_{414} to block the signal path momentarily. When a desired signal and a noise pulse are received simultaneously, the blanking action is not impaired, because the relative amplitude difference between the desired signal and the noise pulse is still high. The front panel noise blanker level control varies the DC voltage applied to the base of Q_{411} .

AF UNIT (PB-1964)

The IF signal from pin 2 is fed through T_{501} to the ring demodulator, consisting of D_{502} - D_{505} (1S1007), where the IF signal is demodulated into audio, using the carrier signal delivered from Q_{503} (2SC1815Y). The carrier signal is generated by oscillator Q_{514} (2SK19GR), and it oscillates at one of the following frequencies:

USB, CW·RX	8989 KHz
LSB	8986 KHz
CW·TX	8988.3 KHz

The audio signal is then amplified by audio amplifiers Q_{507} , Q_{508} (2SC1000GR), and Q_{509} (μ PC2002), delivering 3 watts of audio output to the speaker.

The audio spectrum is shaped by an active low-pass filter of $f_0 = 2.7$ kHz, -12 dB/octave.

MARKER GENERATOR

A 25 kHz marker signal is provided, for alignment and testing purposes. Marker generator Q_{509} (2SC1815Y) generates a basic 3200 kHz signal, which is divided into 25 kHz multiples by Q_{506} (MC14024B), a binary counter.





TRANSMIT CIRCUIT

SSB MODE

The output from microphone jack J_2 is fed through the MIC GAIN control VR₃₈ to pin 8 of the AF UNIT.

AF UNIT (PB-1964A)

The speech signal from pin 8 is amplified by microphone amplifier Q_{502} (TA7063P) and fed through relay RL₅₀₁ to the ring modulator, $D_{502} - D_{505}$, where the speech signal modulates the carrier signal delivered from Q_{513} . The resulting double sideband signal is fed to the IF UNIT.

IF UNIT (PB-1963)

The 8.9875 MHz double sideband signal is amplified by Q_{401} (3SK51-03) and passed through sideband filter XF₄₀₁ by diode switches D_{403} , D_{409} (1S1555), D_{405} , and D_{407} (1S1007). Here the signal is converted to a single sideband signal by removal of the unwanted sideband.

The signal is then fed to buffer amplifier Q_{402} (2SK19GR). When the RF speech processor is OFF, diode switches D_{411} and D_{412} (1S1555) feed the IF signal to IF amplifier Q_{405} (3SK51-03). When the RF speech processor is ON, the SSB signal is amplified by buffer amplifier Q_{402} (2SK19GR) and further amplified by limiter Q_{403} (TA7060P), where signals that exceed the preset clipping level are sliced out.

This highly clipped SSB signal is amplified by buffer amplifier Q_{404} (2SC372Y) and passed through a selective filter, XF₄₀₃, which removes RF harmonics that result from signal clipping. The signal is then fed to IF amplifier Q_{405} , and subsequently delivered to the RF UNIT. The front panel COMP LEVEL control, VR₄, controls the voltage at gate 2 of Q_{401} , thus setting the processor level.

The return of the grid circuit of the final amplifier tubes is fed to Q_{406} (2SK19BL), which produces ALC voltage. This voltage is fed to gate 1 of Q_{405} ,

controlling the gain of this stage. When the RF processor is off, ALC voltage is also fed to gate 1 of Q_{401} . Q_{407} (2SA564) amplifies the ALC voltage for indication on the front panel meter.

RF UNIT (PB-2154)

The IF signal from J₁₀₂ is delivered to the Schottky barrier diode module Q₁₀₂ (ND487C2-3R), where the IF signal is mixed with a local signal delivered from Q₁₀₄ (2SC2407), producing the RF output signal. The RF signal is then amplified by Q₁₀₅ (2SC2407) and Q₁₀₆ (3SK40M), and fed through diode switch D₁₁₀ (1S1007) to the DRIVE UNIT.

DRIVE UNIT (PB-1714), PA UNIT (PB-1715)

The RF signal is amplified by driver V_{1601} (12BY7A), and delivered to PA UNIT final amplifier tubes V_{1701} and V_{1702} (6146B). The output from the final tubes is fed to the antenna jack.

A portion of the RF signal is coupled through C_{14} to the cathode of the 12BY7A driver, for the purpose of improving the linearity of the final amplifier. This technique is known as RF negative feedback.

CW MODE

For CW, the 8.9883 MHz carrier is generated by oscillator Q_{514} at the frequency set by X_{504} . The carrier signal is fed through buffer Q_{513} and fed to the ring modulator. The same carrier frequency is used in the tune mode.

DC voltage is applied through diode switch D_{517} (1S1555) and relay RL_{501} , unbalancing the ring modulator for CW operation. The carrier signal is then fed to the IF UNIT. The signal path is identical to that on SSB, up to the DRIVE UNIT.

DRIVE UNIT (PB-1714), PA UNIT (PB-1715)

Keying of the transmitter is accomplished by changing the bias voltage to the driver and final tubes. During "key up," the tubes are cut off by application of -35 volts to V_{1601} and -110 volts to V_{1701} and V_{1702} . These cutoff voltages are

reduced to -0.1 volt and -60 volts, respectively, during "key down" conditions.

The key is connected to the KEY 2 terminal on the RECT B board, PB-1968. When the key is closed, the base of Q_{1001} (2SA733) is grounded, causing Q_{1002} (2SC372Y) to conduct. The base of Q_{1003} (2SA639) is thus set to 0 when the transistor conducts. Under these circumstances, the bias voltage applied to V_{1601} , V_{1701} , and V_{1702} places these tubes in the normal operating condition.

VOX circuit

A portion of the microphone input signal is amplified by three stages of Q_{503} (MC3403P), which drive the VOX control gate, Q_{504} (SN74LS123N). The output from pin 13 of Q_{504} is fed to the base of Q_{512} (2SC1383), switching the VOX relay on and off according to the presence or absence of a speech signal.

A portion of the speaker output is detected by D_{510} and D_{511} (1N60), providing a bucking voltage which is fed to Q_{503} , preventing the speaker output from tripping the VOX.

The VOX delay may be set by adjusting VR_{2b} for the desired delay time.

CW SIDETONE

CW sidetone oscillator Q_{511} (2SC373) oscillates at a frequency of approximately 800 Hz. The output from Q_{511} is amplified by the final audio amplifier, Q_{501} , for delivery to the speaker. The output from the sidetone oscillator is also fed to VOX amplifier Q_{503} , providing semi-break-in operation for CW.

AM MODE

The speech signal from the microphone is amplified by Q_{2401} (2SC732GR) and Q_{2402} (2SC1815Y) and passed to modulator Q_{2405} (2SC380Y), where the speech signal modulates the AM carrier signal at 8988.3 kHz delivered from Q_{2404} (2SK19GR). The modulated signal is amplified by Q_{2406} (3SK51) and delivered to transmit mixer Q_{105}/Q_{106} .

COMMON CIRCUITS

VFO UNIT (PB-1440B-3420)

A modified Colpitts-type oscillator is used to generate a 5.0 - 5.5 MHz VFO signal, thus producing a 500 kHz tuning range. The oscillator signal generated by Q_{801} (**2SC372Y**) is varied by VC_{801} , which is geared to a precision-built dial tuning mechanism. VC_{801} consists of two sections; the sub-blades compensate for the capacitance variation of the main blades, which may result from extreme temperature change.

Varactor diode D_{801} (1S2209) may be varied by tuning L_{806} , providing ±2.5 kHz offset from the dial frequency (clarifier).



The VFO signal is amplified by buffer amplifiers Q_{802} (2SK19GR) and Q_{803} (2SC372Y), and passed to the PREMIX UNIT.

NB & FIX UNIT (PB-1961)

Two crystal-controlled channels are provided for operation with this transceiver. The oscillator signal is generated by Q_{203} (2SC372Y) and amplified by Q_{204} (2SC372Y), and delivered to the PREMIX UNIT. Crystals X_{201} and X_{202} oscillate in the 5.0 - 5.5 MHz range.

PREMIX LOCAL UNIT (PB-2153)

Crystal oscillators $Q_{601}-Q_{612}$ (2SC380Y) generate the premix local signal at the frequencies shown in Table 3. Diode switches $D_{601}-D_{612}$ (1S1555) select the proper local signal for the band in use. The local signal is then delivered to the PREMIX UNIT.

PREMIX UNIT (PB-2152)

The premix signal is produced at Q₃₀₃ (SN76514N), a double-balanced mixer, where the premix local signal from Q₆₀₁-Q₆₁₂ is mixed with the VFO or crystal controlled 5 MHz signal. The premix output frequencies are shown in Table 3. The premix signal is passed through bandpass filter T₃₀₁-T₃₀₄, and amplified by Q₃₀₁, Q₃₀₂ (2SC1923R). The amplified signal is then fed to the RF UNIT, where the signal is further amplified by Q₁₀₇ for delivery to the transmitter and receiver mixers.

		XCO Frequency	PREMIX OUT Frequency
160 m	X 601	15.9875MHz	10.4875~10.9875MHz
80 m	X 602	17.9875MHz	12.4875~12.9875MHz
40 m	Х 603	21.4875MHz	15.9875~16.4875MHz
30 m	X 604	24.4875MHz	18.9875~19.4875MHz
20 m	X 605	28.4875MHz	22.9875~23.4875MHz
17 m	Х 606	32.4875MHz	26.9875~27.4875MHz
15 m	X 607	35.4875MHz	29.9875~30.4875MHz
12 m	X 608	38.9875MHz	33.4875~33.9875MHz
10 m A	X 609	42.4875MHz	36.9875~37.4875MHz
10 m B	X 610	42.9875MHz	37.4875~37.9875MHz
10 m C	X 611	43.4875MHz	37.9875~38.4875MHz
10 m D	X 612	43.9875MHz	38.4875~38.9875MHz







COUNTER UNIT (PB-2086A-3420/PB-2098)

The local oscillator signal is applied to Large-Scale Integrated Circuit (LSI) chip for display on the front panel digital display.

The premix signal as shown in Table 4 from the LOCAL Unit, is amplified by Q_{2303} (2SC1674) and delivered to the LSI counter chip, Q_{2312} (MSM95 20RS). A portion of the output from Q_{2303} is amplified by Q_{2304} (2SC1815Y) and fed to gate 2 of Q_{2301} controlling the gain of those amplifiers.

The output from the LSI is fed to the display. The output from pins 24 through 30 is delivered to segment drivers $Q_{2313}-Q_{2319}$ (2SA952L) and digit drivers $Q_{2306}-Q_{2311}$ (2SA952L) through a dynamic drive configuration. Display is performed by $D_{2201}-D_{2206}$ (HP5082-7623), seven-segment light-emitting diodes.

Provided by http://www.yaesu-museum.com

Downloaded by Amateur Radio Directory

	Nominal Premix Local Frequency	LSB	USB	CW, AM
160m	10.4875-10.9875(MHz)	10.486-10.986(MHz)	10.489-10.989(MHz)	10.4883-12.9883(MHz)
80m	12.4875-12,9875	12.486-12.986	12.489-12.989	12.4883-12.9883
40 m	15.9875-16.4875	15.986-16.486	15.989-16.489	15.9883-16.4883
30 m	18.9875-19.4875	18.896-19.486	18.989-19.489	18.9883-19.4883
20m	22.9875-23.4875	22.986-23.486	22.989-23.489	22.9883-23.4883
17 m	26.9875-27.4875	26.986-27.486	26.989-27.489	26.9883-27.4883
15 m	29.9875-30.4875	29.986-30.486	29.989-30.489	29.988330.4883
12m	33.4875-33.9875	33.486-33.986	33.489-33.989	33.488333.9883
10m A	36.9875-37.4875	36.986-37.486	36.989-37.489	36.9883-37.4883
10m B	37.4875-37.9875	37.486-37.986	37.489-37.989	37.4883-37.9883
10m C	37.9875-38.4875	37.986-38.486	37.989-38.489	37.9883-38.4883
10m D	38.4875-38.9875	38.486-38.986	38.489-38.989	38.4883-38.9883

Table 4





DISPLAY UNIT PB-2098



DISPLAY/COUNTER UNIT

POWER SUPPLY

The power supply is designed to operate from 100/110/117/200/220/234 volts AC. A DC-DC converter is an available option. providing operation from 13.5 volts DC. Insertion of the appropriate power plug into the rear panel receptacle makes the necessary connections for AC or DC operation.

When the transceiver is operated from a DC 13.5 volt power source, using the optional DC-DC converter, transistors Q_{3201} and Q_{3202} (T20A6) function as a low frequency oscillator, providing AC voltage at approximately 80 Hz to the power transformer. All of the tube heaters receive their power through the HEATER switch on the front panel. When the HEATER switch is OFF, voltage is still supplied to the receiver section, thus allowing continuous reception with reduced power consumption. The heaters of the two 6146B are connected in series to operate at 12 volts DC.

The 14 volt AC power delivered from the secondary winding of the power transformer is rectified by D_{905} and D_{906} (V06B). Voltage regulators Q_1 (2SB616), Q_{901} (78L12), and Q_{903} (2SA495)



stabilize the DC supply at 12 volts. The supply voltage is further stabilized at 8 volts by Q_3 (μ PC14308) for delivery to the counter, AF, and other units. The 6 volt supply for the VFO is provided through zener diode D₉₀₈ (WZ061), while the 5 volt supply for the TTL integrated circuits is provided by Q₅₀₅ (78L05).

The power amplifier plate voltage of +800 volts is supplied from the bridge-controlled doubler, located on the RECT. A UNIT, and consisting of $D_{901} - D_{904}$ (10D10).

÷

AC 190 volts is rectified by D_{1002} (10D10), producing 210 volts for the screen grid supply of the power amplifier tubes. The screen grid voltage for the driver tube is obtained by rectifying 250 volts AC at D_{1001} (10D10), producing 300 volts. This voltage is dropped to 180 volts by a resistor for delivery to the driver tube screen grid.

The 120 volt AC power from the transformer secondary winding is rectified by D_{1003} (10D10) in order to obtain -140 volts for the driver and final amplifier tube grid bias.





TOP VIEW

SELECT SW BOARD



MAINTENANCE AND ALIGNMENT

WARNING

DANGEROUS VOLTAGES ARE PRESENT WITHIN THIS TRANSCEIVER. USE EXTREME CAUTION WHEN WORKING ON THE TRANS-CEIVER WITH THE COVERS REMOVED. DIS-CHARGE ALL CAPACITORS BY SHORTING THEM TO GROUND WITH AN INSULATED SCREWDRIVER AFTER POWER HAS BEEN REMOVED. OBSERVE NORMAL SAFETY PRE-CAUTIONS AT ALL TIMES.

CAUTION

Never operate this transceiver in the transmit mode without a matched antenna or dummy load connected to the antenna receptacle on the rear panel. It is possible to damage the final amplifier tubes and the pi network components if the transmitter is operated without the proper load termination.

GENERAL

This transceiver has been carefully aligned and tested at the factory. With normal use, it should not require other than the usual attention given to electronic equipment. Service or realignment of a major component may require substantial adjustment; under no circumstances, though, should realignment be attempted unless the operation of the transceiver is fully understood, the malfunction has been carefully analyzed, and the fault has definitely been traced to misalignment. Sudden difficulties are almost always caused by component failure rather than misalignment.

Service work should only be performed by experienced personnel, using the proper test equipment.

EQUIPMENT REQUIRED

(1) RF Signal Generator: Hewlett-Packard Model 606A or equivalent, with one volt output at 50 ohms, and frequency coverage to 30 MHz.

- (2) Vacuum Tube Voltmeter (VTVM): Hewlett-Packard Model 410B or equivalent, with an RF probe good to 40 MHz.
- (3) Dummy Load: Yaesu Model YP-150 or equivalent, with 50 ohm non-reactive load impedance, rated to 150 watts average power.
- (4) AF Signal Generator: Hewlett-Packard Model 200AB or equivalent.
- (5) A general coverage receiver covering 3 to 30 MHz, with a 100 kHz crystal calibrator.
- (6) A frequency counter, Yaesu Model YC-500 or equivalent, with resolution to 0.01 kHz and frequency coverage to 30 MHz.
- (7) An oscilloscope, Hewlett-Packard Model 1740A or equivalent.

AF UNIT ALIGNMENT

VOX Circuit

A. Antitrip level setting

- 1. Tune in a signal on the FT-101ZD receiver, and adjust the AF GAIN control for a normal listening level. Position the microphone near the speaker, with the MODE switch in the SSB mode. Increase the VOX GAIN control on the front panel until the speaker output causes the VOX relay to switch the transceiver to transmit. Set the ANTITRIP control VR₀, located on the rear apron, to the point that will just prevent the speaker output from tripping the VOX relay.
- 2. Now place the microphone in the normal operating position, and speak into the microphone to see if your voice will activate the VOX relay. If not, VR, may be advanced too far.

B. VOX relay delay setting

 Adjust the DELAY control VR_{2b}, located on the front panel, for the desired delay time. This may require a different setting for phone and CW operation, owing to differing operating techniques. For CW or phone operation using a footswitch, the VOX GAIN control may be rotated fully counter-clockwise to the PTT position.

CW Sidetone

1. The CW sidetone level may be adjusted by means of VR_{10} , located on the rear apron.

Marker Frequency setting

- Preset the controls as follows: BAND 30 m DIAL 10 MHz PRESELECT . Peaked for maximum response MODE TUNE
- Place the NB/MARK switch in the MARK position. Tune in the WWV or JJY signal, and adjust TC₅₀₁ for an exact zero beat with the carrier of the incoming signal.

Carrier Frequency Adjustment

A. SSB Carrier Point

- 1. Tune up the transmitter on 20 meters, LSB mode, into a dummy load. Apply a 1 kHz audio signal to the microphone input, and adjust the audio generator output until the transmitter power output is 60 watts, as indicated on the dummy load wattmeter.
- Shift the audio generator output frequency to 300 Hz, without changing the output level. Adjust TC₅₀₃ for a power output reading of 15 watts on the wattmeter.
- 3. Shift the MODE switch to USB. Adjust TC_{504} for an identical 15 watt reading on the wattmeter.



AF UNIT(PB-1964)

4. Recheck the LSB adjustment, as well as the carrier balance adjustment, after performing the carrier point alignment. The background noise, when switching between USB and LSB, should not change.

B. Carrier Balance

- 1. Tune up the transceiver on 20 meters, USB mode, into a dummy load. Set the main tuning dial to 14.250 MHz. Connect the RF probe of the VTVM to the antenna jack. Disconnect all microphones, etc., from the microphone jack.
- Activate the transmitter by placing the VOX GAIN control into the MOX position. Adjust VR₅₀₁ and TC₅₀₂ for a minimum VTVM reading.
- 3. If a VTVM is unavailable, use an external

monitor receiver, tuned to the transmitter frequency, and adjust VR_{501} and TC_{502} for a minimum S-meter reading on the external receiver.

- 4. This adjustment should be repeated several times on LSB and USB, in order to ensure complete carrier nulling.
- C. CW Carrier Point
- 1. Connect a frequency counter to TP_{402} , located on the IF UNIT. Place the MODE switch in the TUNE position.
- Adjust TC_{sos} for a frequency counter reading of exactly 8988.3 kHz.
- 3. When using the optional CW filter, a substantial loss on transmit, when in the CW-N position, may indicate the need for adjustment as indicated in steps 1 and 2.



IF UNIT(P8-1963)
IF UNIT ALIGNMENT

S-Meter Sensitivity Adjustment

- 1. Set the BAND switch to 20 meters, the main dial to 14.250 MHz, and set the RF GAIN fully clockwise.
- 2. Set the signal generator to 14.250 MHz, and set its output to 6 dB. Tune the signal generator signal on the receiver, and peak the preselector for maximum signal strength. The S-meter should just begin to move with the 6 dB input.
- 3. Adjust VR₄₀₃ for a reading of 0 on the Smeter.
- 4. Set the generator output to 100 dB, and adjust VR_{405} for a reading of S9 + 60 dB on the S-meter. Confirm that the preselector is peaked.
- 5. Return the signal generator output to 6 dB, and recheck the adjustment of VR402.

Variable IF Bandwidth Alignment

 Set the controls as follows: BAND 20 m DIAL 14.200 MHz RF GAIN Fully clockwise WIDTH switch .. OFF MODE USB Deck the prescleater for mening

Peak the preselector for maximum response against the marker signal or background noise.

- 2. Connect the frequency counter to TP_{411} . Adjust VR₁₅₀₁ for a reading of exactly 19.7475 MHz.
- Place the WIDTH switch ON. Make sure that
 the WIDTH control is exactly in the 12 o'clock position. Adjust VR₄₀₄ for a reading of exactly 19.7475 MHz on the frequency counter.
- 4. Switch between USB and LSB, and observe the background noise. If there is any difference, adjust VR₁₅₀₁ until the background noise is the same.

ALC Meter Alignment

- 1. On any band, set the MODE switch to USB. Set the meter switch to ALC.
- 2. With no speech input, activate the transmitter. Adjust VR_{403} for a 0 reading on the ALC meter scale.



RECTIFIER B UNIT

Bias Adjustment

- 1. Set the MODE switch to USB or LSB, and set the MIC GAIN control fully counterclockwise.
- Place the METER switch in the IC position, and set the VOX GAIN control to VOX. Adjust the BIAS control located on the RE-CT, B UNIT (PB-1968) VR1001, for a reading of 50 mA. For 10 watt models, the correct meter reading is 25 mA.



RECT B UNIT(PB-1968)

VFO UNIT

The VFO UNIT is very critical in its adjustment. As well, this is not an area which should ever require alignment. Questions regarding drift. etc., usually can be traced to other areas of the transceiver (instability in the supply voltage, etc.). For this reason, all cases regarding VFO repair should be referred to an experienced service technician.

The following components are of interest from a service standpoint:

 TC_{B01} is the band set trimmer.

 TC_{802} is the VFO level set trimmer.

To confirm proper VFO injection, connect the VTVM to the VFO output. Adjust TC_{802} for a reading of 100 mV.



BAND	CRYSTAL	FREQUENCY	TRANS- FORMER
160m	X 801	15.9875MHz	T 601
80 m	X 602	17.9875	Т 602
40 m	Xeos	21.4875	T eos
30 m	X 804	24.4875	T 604
20 m	X 608	28.4875	T 605
17 m	X 606	32.4875	T 806
15 m	X 607	35.4875	T e07
12m	X 808	38.9875	T sos
10 m A	Xeos	42.4875	Teos
10m B	X 610	42.9875	T #10
10m C	X 611	43.4875	Ten
10m D	X 612	43.9875	T 612

Table 6

NB-FIX UNIT

Fixed Channel Frequency Alignment

When the optional fixed channel crystals are being used, they may be placed exactly on the correct frequency by adjusting TC_{201} (for channel 1) and TC_{202} (for channel 2). Confirmation of the correct frequency may be made with an external receiver or by loosely coupling a probe from the frequency

counter to the transmitter output. A 1-turn loop is usually sufficient to provide indication on the counter.

PREMIX LOCAL UNIT

Premix Local Alignment

- 1. Connect the RF probe of the VTVM to pin 1 of MJ₃.
- 2. Refer to Table 6, and adjust the appropriate transformer for a level of 300 mV for each band and crystal, as shown in the table.

PREMIX UNIT

For this alignment, a wideband (not peak) sweep generator, as well as an oscilloscope, should be used.

- Press the EXT select switch. Apply 5.0 5.5 MHz sweep output to the VFO output terminal at the rear apron external VFO jack. Connect a high-impedance probe of an oscilloscope to J₃₀₁.
- 2. Adjust the transformers shown in Table 7 for a flat response across the entire passband. If you have never adjusted a bandpass filter previously, this may take some practice. Perform the adjustments on each band, according to the chart.

BAND	TRANS- FORMER	PASSBAND
160 m	T 301, T 302	10.4-11.0(MHz)
80 m	T 303, T 304	12.4-13.0
40 m	Тзов, Тзре	15.9-16.5
30 m	T 807, T 308	18.9-19.5
20 m	Тзов, Тзіо	22.9-23.5
17 m	T 311, T 312	26.9-27.5
15 m	Tais, Tai4	29.9-30.5
12 m	T \$15, T 316	33.5-34.0
10 m A	T 317, T 318	36.9-39.0

AM UNIT

Table 7

- 1. Set the BAND switch to 40, the MODE switch to AM, and the DRIVE control to the 3 o'clock position. Tune up the transmitter in the usual fashion. Now adjust the core of T_{2401} for maximum power output into the dummy load/wattmeter.
- 2. Connect a frequency counter to TP_{2402} . Adjust TC_{2401} for a counter reading of exactly 8988.3 kHz while transmitting.
- 3. Connect the RF probe of the VTVM to TP_{2401} , and adjust TC_{2402} for a reading of 50 mV while transmitting.

- 38 -

1



- 39 -

TRANSMIT RF/IF TRANSFORMER ALIGNMENT

- (1) Connect a dummy load to the antenna jack, and connect an audio signal generator to the microphone input. Tune up the transmitter at 14.2 MHz, and adjust the audio generator output for approximately 50 watts output into the dummy load, single-tone, SSB mode.
- (2) Peak T₄₀₁ T₄₀₃ and T₄₀₅ (IF UNIT) for maximum power output. Switch the RF processor on, and adjust the COMP LEVEL control for approximately 50 watts output. Peak T₄₀₄ for maximum power output.



RF UNIT (PB-2154)

RECEIVER RF/IF/NB TRANSFORMER ALIGNMENT

ŝ

- Tune in the marker generator signal at 14.2 MHz, with a dummy load connected to the antenna jack. Peak the preselector for maximum S-meter indication.
- (2) Peak T104 (RF UNIT) for maximum S-meter indication.
- (3) Peak $T_{406} T_{411}$ and $T_{413} T_{415}$ for maximum S-meter indication.
- (4) Connect the RF probe of a VTVM to the collector of Q_{202} (NB-FIX UNIT). Reduce the RF GAIN control somewhat, and tune T_{201} and T_{202} for a dip in the VTVM indication. If no dip is observed, reduce the RF GAIN control further.

CLARIFIER ALIGNMENT

- 1. Tune in the marker generator signal on any band, and peak the preselector on the marker signal.
- 2. With the CLARIFIER control OFF, make sure that the CLARIFIER knob is exactly at the 12 o'clock position. Note the tone of the marker signal.
- 3. Switch the RX CLARIFIER to ON, and observe the tone of the marker signal. If it is different from when the clarifier was turned off, adjust VR_{1801} for an identical tone with the CLARIFIER knob exactly on the zero mark.





COUNTER UNIT (PB-2086A)

FINAL AMPLIFIER NEUTRALIZATION

Important Note: For this alignment, use a NON-METALLIC tuning wand.

- 1. Set the BAND switch to 10C, set the tuning dial to 29 MHz, and tune into a dummy load for approximately 70% full output power.
- 2. Set the METER switch to IC, and observe the dip in the cathode current. The dip should occur at the same point that maximum power output (measured on the dummy load wattmeter) occurs. If this is not the case, adjust TC_1 , located inside the final amplifier cage, for the required coincidence of maximum power output and dip on the IC meter.
- CAUTION: HIGH VOLTAGES ARE PRESENT ON THE UNDERSIDE OF THE CHASSIS AND INSIDE THE FINAL AMPLIFIER COMPARTMENT. USE GREAT CARE WHILE MAKING ADJUSTMENTS IN AREAS OF EX-POSED WIRING.
- Note: The final amplifier enclosure must be in place to provide the required RF shielding during the neutralization procedure.



Final Amplifier Compartment



RECT A UNIT(PB-1967)

	MAIN	CHASSIS	C5	K30279062	Dipped mica	500 WV	3000 pF
Symbol No.	Parts No.	Description]		(DM)	9-302K5)
		IC, TRANSISTOR	C59, 66	K31306800	Moulded mica	1 KWV	80 pF
Q2	G3104960Y	TR 2SA496(Y)	C17	K02279001	Ceramic	500 WV	
01	G3206160F	" 2SB616R(S)	C10	K02279002	"	**	5 pF
Q4	G34023500	······································	C18	K02279003	.,		47 pF
Q3	G1090070	IC µPC14308	C11	K00279001			200 pF
Q5	G1090080	" μPC78L08	C20	K00279002	10		470 pF
-			C16	K0030003	**	1 KV	3 pF
			C15	K02309002			5 pF
		DIODE	C14	K02309003			100 pF
DI	G2090029	Ge 1N60	C3	K00329002	"	1.5 KW	V 460 pF
D2-5	G2015550	Si 1S1555	C9	K00359001	14 · ·	3 KV	100 pF
D6	G2090001	" 10D1	C1	K12359001			1000 pF
			C73-75	K13170102		50WV	0.001 µF
	1		C29, 34, 35,	K13170103		50 WV	0.01 µF
	+		41,64			0 Q V	
	1	RESISTOR	C12, 22-24,	K13170473			0.047 µF
R22, 24	J01245220	Carbon film $1/4W$ TJ 22Ω	39, 40, 56,	1 101/04/3			VICH I ME
R23	J00245330	" " VJ 33 Ω	58, 60, 68,		1		
R14	J01245560	" " ΤJ 56 Ω	69		1		
R7, 11	J01243300	<u>13 36 12</u> """"""" 100 ກ	C27, 28, 36	K12279004		500 10	0.0047 µF
R18	J01245101 J01245821	¹⁰⁰ Ω	C30,32,33,54,	K12279004		<u> 300 w v</u>	0.004 / μF
R16 R4, 5	J01245102	<u>" " " 1 kΩ</u>	55, 61	A122/9002			0.01 μΓ
R4, 5	J01245102 J01245152	<u>1 κω</u>	C2, 25, 26	K12329002	"	1 4 222	0.0047 µF
R19		" " " 1.8 kΩ	C2, 23, 26			1.4 K V	
R17	J01245182	^{1.6 KM}	C42-51	K12329001 K21270002	Feed thru		0.01 µF
R20 ·	J01245222 J01245474	<u>2.2 Kγ</u>	042-51	K21270002			0.001 µF
R20 ·	J10276100	Carbon composition 1/2W GK 10 Ω	C63	K40120476		-L2H102	
R9, 10		· · · · · · · · · · · · · · · · · · ·	ŧ		Liectrolytic	16 WV	47 µF
	-	"" " IW " 56 Ω	C72	K40120107		50WV	<u>100 µF</u>
(with L5, L6)	1100076101	" " " 100.0	C65	K40120337			330 µF
R3	J10276101	100.37	C70	K40120106			10 µF
R1 R25	J10276222	2.2 KM	C67	K40100336		10 WV	33 µF
K25	J30356150	Cement 3W 15 Ω	C71	K50177104	Mylar	50 WV	0.1 µF
		· · · · · · · · · · · · · · · · · · ·					
	· · · · · · · · · · · · · · · · · · ·						
VD	ICORDONALS	POTENTIOMETER			VARIABLE CA	PACITO	
VR1	J60800035	VM11AB06A5M1112 10 kΩB	VC1	K90000026			250 pF
VR2	J62800032	DM10A039A 500 kΩB/20 kΩB	VC2	K90000016	C134E125		
VR3	J62800033	DM10A039A 5 kΩA/5 kΩB					· · · · · · · · · · · · · · · · · · ·
VR4	J60800043	VM10A592A 5 kΩA			TRIMMER CAP		
VR5, 6	J60800036	VM10A592A 5 kΩB	TC1	K91000007	TSN120C 10P	x 2	
VR7	J62800034	DM10A39A 5 kΩB/5 kΩA		í	=		
VR8	J60800037	VM10A654A 1 kΩB					
VR9, 10	J60800038	VM10A654A 5 kΩB					
VR11	J60800039	VM10AB08A 5 kΩB	·		INDUCTOR		
	ļ		L1	L0020534C			
			L2	L0020611			
			L3	L1020065			
	ļ.	CAPACITOR	1.4	L1020064			
		Dipped mica 500 WV 5 pF	L5, L6	L1020308A			
C13, 19, 21	K30276271	" " 270 pF	(R9, R10)				
		(LCQ1727271K5)	L7		EL0710-251K	250 µ	Н
C8	K30276331	" " 500 WV 330 pF	L8	L1190017	FL-5H-102J	1 m	Н
		(DM-15-331K5)	19	L0020705			
C7	K30276621	" " 500 WV 620 pF					
		(DM19D621K5)		·			
C6	K30279052	" " 500 WV 1100 pF					
C6	K30279052						

43 -

.

	1	TRANSFORMER			· ···· ···· · ···· · ·····
TI	L0020544				
T2, T3	L0020074	1			
	·				MULTIJACK
			MJ1	P4090001	121S-10B-105A
			MJ2	P4090007	220D-20B-205A
			MJ3	P4090002	121S-14B-105A
		METER		14090002	1213-14B-105A
M1	M0090002				
	1400,0001	1-1-5-02			
		· · · · · · · · · · · · · · · · · · ·			
			P1	B1000070	PLUG
		SPEAKER	P2	P1090079	
SP1	M4090005	SA-92Y 4Ω 3W	P3	P1090080	
	144070005	13A-921 412 5 W	P4	P1090082	
· · · · ·		· · · · · · · · · · · · · · · · · · ·		P1090086	
		· · · · · · · · · · · · · · · · · · ·	P5	P1090082	
			P6	P1090075	
PT1	L3030028	POWER TRANSFORMER	P7	P1090072	
F11	123030028	52-74	P8	P1090082	
	· / · ·		P9	P1090079	
			P10	P1090083	5047-16A
······································	+	·····	P18	P1090070	5047-03A (with wire T9201420A)
	+	RELAY	P11, 14, 22	P0090045	SQ4052
RLI	M1190004	FRL-263 D012/04CS01	P15	P0090002	SI5908
RL2	M1090002	MX2P	P16	P0090005	SI-7502
		· · · · · · · · · · · · · · · · · · ·	P19	P1090070	5047-03A
		· · · · · · · · · · · · · · · · · · ·	P20	P1090075	5047-08A
			P21	P0090075	P-7015
		RELAY SOCKET			
RLS1	M1490010	263H204			FUSE
RLS2	M1490001	PX08	F1	Q0000005	5 A (100V-117V)
				Q0000004	3 A (200V-234V)
• • • • • • • • • • • • • • • • • • • •	<u> </u>				· · · · · ·
		SWITCH			
\$1	N0190070	#250041 (SR\$)			FUSE HOLDER
\$2	N0190071	#250044 (RS2-4-11)	FH1	P2000001	SN1001 #2
53 *(Lot 1-7)	N0190025	ESR-E485R20	FH2	P2000003	F3265
53 *(Lot 8→)	N0190037	ESR-E486R20		-	
4, 5	N7090005	WD9223			
					······································
					PILOT LAMP
	1	COOLING FAN	PL1	Q1000026	
ANI	M2090001	2\$B10A	PL2-5	Q1000033	M1041.5.9 (BF311-04071A)
				21000033	K0252-6-8 (BQ054-32732B)
		· · · · · · · · · · · · · · · · · · ·			
	<u> ·· -−</u> {	RECEPTACLE	· · · · · · · · · · · · · · · · · · ·	╡───~┥	
1	P1090004	SG7814		05000010	
3	P1090134	SG7627		Q5000010	Thru terminal FT-SM1
2	P0090011			Q4000002	A339 (HV)
4	P1090033	D6-701B00		Q6000042	Terminal block ML-3182 20P
5	P1090033	5047-08 (with wire T9203200)		Q6000004	Term nal board 1L2PS (2-0)
6				Q6000007	" 1L3PS (2-0-1)
7	P1090014	S17501-1		Q6000	"1L5PS (4-0-1)
8	P1090028	M-BR-06B		Q6000003	" 1L2PS (1-0-1)
	P1090040	SA607B00		Q6000008	" IL3P (3-0)
	P1090025	STR-01			" 1L3PS (1-0-2)
15	P1090005	SG-8050		L	
16	P1090045	AC9-PF	· · · · · · · · · · · · · · · · · · ·		
17	P0090047	QS-DB6-ML			
19	P1090111	J-7015	.*	1	

- 44 -

	****				CAPACITOR
PB-1390	F0001390	P.C. Board	C138	K02179003	
D9	G2090060	GD4-203-SRD	C106	K02172040	
		· · · · · · · · · · · · · · · · · · ·	C125, 126	K00175680	
			C103	K00175101	100 bi
			C102, 104,	K13170103	3
			116, 119-		
			121, 130,		
			131, 135,		
			140		
-			C101, 105,	K13170473	0.047 μF
	F	IF UNIT	107-115,	1	
Symbol No.	Parts No.	Description	117, 118,		
PB-2154	F0002154	Printed Circuit Board	122-124,		
	C0021540	P.C.B. with components	127129,	Ì	
			132-134,		
	1		136, 137,		
	:	IC, FET & TRANSISTOR	139		
Q102	G2090135	IC (Ring Module) ND487C2-3R			TRIMMER CAPACITOR
Q106	G4800400M		TC101	K91000019	
Q101	G4800510C			10100019	10 pr
Q103	G3090019	" J310			INDUCTOR
Q104, 105	G3324070	TR 2SC2407	L107	L0020491	0.32 µH
<u></u>	000001010	2302707	L108, 112	L1190033	0.32 µH FL5H-820K 82 µH
	+		L102, 103,	L1190033	
	+		105, 106,	L1190010	FL5H-101K 100 µH
	+	DIODE			
D110	G2010070		113, 114	1.11000220	
			L104, 109,	L1190020	FL5H-151K 150 µH
D103, 104	G2015550	Si 1\$1555	111		
D101, 102,	G2090027	15853	L101, 110,	L1190038	FL5H-271K 270 µH
105-109			115		
		· · · · · · · · · · · · · · · · · · ·		i	-
<u> </u>				7	TRANSFORMER
			T101-103	L0020788A	
	10001000	RESISTOR	T104	L0020221	
R122, 131,	J00245479	Carbon film ¼W VJ 4.7 Ω			JACK
R109, 110,		10 Ω	J101-103	P1090018	SQ-3081
115, 116,					
124, 125		· · · · · · · · · · · · · · · · · · ·			IX UNIT
R135	J00245560	" " 56 Ω	Symbol No.	Parts No.	Description
R106, 1 07,	J00245101	″″″″″ 100 Ω		C0019610	NB-FIX unit with components
113, 114,			PB-1961B	F0001961B	P.C. Board
139, 140		·		1	
108, 117,	J00245121	"""""120 Ω	1		TRANSISTOR
126			Q201-204	G3303720Y	2SC372Y
121, 130	J00245151	"""""""""""""""""""""""""""""""""""""	Q205, 206	G3315830	2SC1583
123, 132	J00245221	·····································			
136	J00245331				DIODE
119, 128	J00245561		D201-204		Ge 1N60
105, 111,	J00245102	" " " " 1 kΩ	D205-209		Si 1\$1555
112, 120,		1.71			
129	ľ			┝ ── ── <u></u> +	RESISTOR
118, 127	J00245152	·····································	R208,216,224,		
141	J00245222	1.5 KW	-	200245101	Carbon film 1/4W VJ 100 Ω
102	J00245272		230,238,239,	100244222	11 11 17 11 200 m
104, 134		2.7 K32	R204	J00245221	220 12
	J00245562	5.0 K12	R222, 236	J00245471	"""" 470 Ω
	J00245103	10 K32	R231-233,235		<u>" " 560 ก</u>
	J00245183	18 KJ2	R206,215,221,	J00245102	"""""1 kΩ
103, 133	J00245393 J00245225	<u>39 kΩ</u> 2.2 MΩ	234,237		

R210, 240	J00245472	Carbon füm 1/4W VJ	4.7 kΩ		-	RESISTOR	
R205,209,218			5.6 kΩ	R323	J00245100		VJ 10 Ω
R202,203,212,	J00245103	21 44 12 22	10 kΩ	R331	J00245680		·· 68 Ω
214,225,226				R301, 303,	J00245101		<u>΄΄ 100 Ω</u>
R201,220,223	J00245153		15 kΩ	305, 307,	i		100 00
R211,213,219			22 kΩ	309, 311,			
R217	J00245683		68 kΩ	313, 315,		વો	
	100210000	· · · · · · · · · · · · · · · · · · ·	00 64	317, 332,			
······		CAPACITOR	· · ·	333	i i		
C201 216_218	¥30176231	Dipped mica 50WV	330 pF	R322, 324,	J00245221		" 220 0
C234, 236	K30176471		470 pF	327, 328	300243221		″ 220 Ω
C234, 250	K30176471		-	R319, 334	100246152		" 1510
C208, 209	K02175150		820 pF		J00245152	12 11 12	1.5 K12
			15 pF	R329, 330	J00245222		2.2 KM
C206	K00179005	" " SL	20 pF	R302, 304,	J00245103		" 10 kΩ
C204	K00175101		100 pF	308, 310,			
C202,203,205,	K13170103		FµF	312, 314,		1	
211,212,221,				316, 318,			
225-227,	4			321, 325,			
229-233				326			
C207,210,213,	K13170473	" <u>"</u> ().047 µF	R306	J00245153	0 0 0	" 15 kΩ
215,219,220,				R320	J00245333	11 12 17	" 33 kΩ
223,224,228,						POTENTIOMETER	
237				VR301	J50710502	V10K-8-1-2	5 kΩB
C214	K40170105	Electrolytic 50WV	1 μF			CAPACITOR	
C238	K40140475	" 10WV	4.7 μF	C335	K30176271	Dipped mica 50WV	270 pF
				C331	K30176331	0 0 0	330 pF
		TRIMMER CAPACITOR		C311, 315,	K30176561		560 pF
rC201, 202	K91000016	ECV-1ZW 50 x 32	50 pF	319	1		
		····		C323, 327	K30176680	n' n n	680 pF
· · · · · · · · · · · · · · · · · · ·		INDUCTOR	· · · · ·	C301, 305,	K13170103	Ceramic "	0.01 µF
L207, 208	L1190007	FL-4H 1R8K	1.8 µH	309, 313,			0.01 μ.
204-206	L1190016	FL-SH 101K	100 µH	317, 321,			
201-203	L1190017	FL-5H 102K	1 mH	325, 329,			
			A 11187	333, 337-			
· ·		TRANSFORMER	· -	339, 341,			
T201, 202	L0020140	R12-4170					
1201, 202	20020140	K12-170		343, 345			
				351			
				C302, 304,	K13170103	Ceramic 50WV	0.047 μF
				306, 308,			
		CRYSTAL SOCKET		312, 314,			
KS201	P3090025	S-14 2P		316, 318,			
·				320, 322,			
				324, 326,			
				328, 330,			
		MINI CONNECTOR		332, 334,			
	P0090037	5048-08A		336, 340,			
202	P0090038	5048-12A	·····	342, 344			
				C303, 307	K50177102	Mylar "	F 0.001
	PRE	MIX UNIT	· · · ·				
ymbol No.	Parts No.	Description			† · · · · · · · · · · · · · · · · · · ·	INDUCTOR	
	C0021520	PREMIX unit with compon	ents	L302		FL4H-1R8M	1.8 µH
	à	P.C. Board		L303	1	FL5H-220K	22 µH
				L301, 304-	+	FL5H-102K	
		C, FET, TRANSISTOR		1 .	21190017	1 L3N-102K	1 mH
303 0		IC SN76514N		306	+		
				i	++		
	53319230R	TR 2SC1923R				TRANSFORMER	
				T301, 302	L0020500		<u> </u>
				T303, 304	L0020501		
		DIODE		T305, 306	L0020502		
)301-318	G2090027	Si 1SS53					

T309, 3 10	L0020504		XF403	H1100890	x	F8.9HP	
T311, 312	L0020836		XF404	H1100470	8.	9M20A	
T313, 314	L0020837		XF405	H1100900	X	F10GS (X	F-10HW)
T315, 316	L0020838				THERMIST	OR	
T317, 318	1.0020839		TH401	G9090003	D	-33A	
T319	L0020210				RESISTOR		
-			R0517, 0518,	J00245220	Carbon film	1/4W V.	J 22 Ω
_		JACK	0520				
J301	P1090018	SQ3081	R410, 411	J01245101	94 .93	" T.	
P301	P0090045	SQ4052	R402,408,422,	J00245101		" V.) 100 Ω
	·		423,437,439,				
			444,446,463,				
			464,469,475,				
			482,483,497				
	· ·		R419,425,447,	J00245221		** **	220 Ω
		FUNIT	451,486,				
Symbol No.	Parts No.	Description	0507,0508				
	C0019630	IF unit with components	R0502	J00245331	** **	** **	220.11
PB-1963C	F0001963C	P.C. Board		J00245391			<u>390 Ω</u>
	<u> </u>		R443	J00245471			47032
	· · · · · · ·		R474,480,0522		<i>H</i> H		200.11
	+		R467, 468	J00245681		······	080.11
0402	0100000	IC, FET, TRANSISTOR		J00245821		·· ··	040 32
Q403	G1090063	IC TA7060P	R406,416,428,				1 kΩ
Q406	G3800190B	4 · · ·	437,440,442,	1			
Q402,413,414,	G3800190G	" 2SK19GR	449,453,457,	1 1			
419, 425	G4800510C	" 25K51.03	459,462,488,				
Q401,405,412, 415, 416	G4800310C	" 3SK51-03					
Q408	G3090019	" J310	0506,0515	100246122			1.210
Q407, 420	G3105641	TR 2SA564A	R429 R495	J00245122			1.2 kΩ
Q404,409,410,			R495 R0516	J00245152 J01245152			<u>1.5 kΩ</u> 1.5 kΩ
417, 418,	0.5007.201	2000/21	R454,455,458,	ا ا	10 40	·· VJ	
422-424		•	0510	500145222		••	2.2 R32
Q421	G3305350A	" 2SC535A	R460	J00245272	<i>11 11</i>		2.7 kΩ
Q411	G3090005	" MPSA13	R401,409,412,	• • • •			3.3 kΩ
•	· · · · · ·		413,431,456,				
·			496,0511				
	*		R426,427,476	J00245472	11 11		4.7 kΩ
		DIODE	R403,445,478,			0 10	5.6 kΩ
D416, 417	G2090029	Ge 1N60	489				
D405-408,	G2010070	" (GB) 1S1007	R434, 450	J00245682	., .,		6.8 kΩ
414.421			R404,407,420,		ei 11	" "	10 kΩ
D401-404,	G2015550	Si 1S1555	421,424,436,				
409-413,			471,477,481,				
419, 424			484,485,491,				
D418	G2022090	Varactor 1S2209	492, 0501,				
D422	G2090040	" FC63	0509, 0512				
D420, 423	G2090010	Zener WZ090	R433	J01245103	## #F	" ТЈ	10 kΩ
			R470	J00245123	0 U	" VJ	12 kΩ
			R415,498,499	J00245153	** **		15 kΩ
			499				
		CRYSTAL	R414	J00245273		<i></i>	27 kΩ
X401	H0100431	HC-18/U 19.7475 MHz	R461,472	J00245473	•• ••	** **	47 kΩ
			0500				
		· · · · · · · · · · · · · · · · · · ·	R405,465,466	J00245104	69 AT	** **	100 kΩ
			R493	J00245154	44 - 41 		150 kΩ
(E40)		CRYSTAL FILTER	R448,452,487,	J00245184		** **	180 kΩ
(F401	H1100860	XF8.9HS	0503, 0505		<u> </u>		
(F402(Option)	H1100880	XF8.9HC		J00245334	• 7)7		330 kΩ

•

·

P DACOL	- 1 TOL DACTO							
R0521 R432		Carbon film		1/4WTJ 270 ks		L0020145	5.2 μH	#220145
	J00245684			" VJ 680 ks	_			
R490	J0024510			" " 1 Mc				
DAFIA	J0024522			" " 2.2 Ms	.1 .			····
R0519	J1024656	′′ сотро	sition	" GK 5.6 MS			TRAN	SFORMER
					T410	L0020150	R12-4	074
					T402,403,404	, L0020140	R12-4	170
					407,409,413	,		
		POTENTIOM	ETER		414			
VR401, 402	J51723102	SR-19R		1 kΩB	T401,406,408	L0020141	R12-4	171
VR403, 404	J51723103	11		10 kΩB	415			
VR405	J51723473			47 kΩB	T405	L0020221		
VR407	J50705502	EVN-A1A-A0	0B53	5 kΩB	T411	L0020460	- <u>+</u>))
VR406	J\$0705504	EVN-A1A-A0	0B55	500 kΩB	T412	L0020209		
			\ \		· · · · · · · · · · · · · · · · · · ·	<u>-</u>		
		CAPACITOR			-	-	-	·····
C477	K3017622	Dipped mica	50WV	220 pF	1	· · · ·		
C445, 472	K0217310		•••	CH 10 pF	t	1	MINIC	ONNECTOR
C488, 492	K0617533			UJ 33 pF	J401	P0090038		5048-12A
C489	K06175390		**	UJ 39 pF	J402	P0090038		5048-13A
C404,421,432				CH 47 pF	J403	P0090040		5048-15A
C487	K06175101			UJ 100 pF		1.0000040	+	JUTO-13A
C459,464,475	K02175101		<i>,,</i>	CH 100 pF	·		· · · ·	
C401,405,406,	1			0.01 µF		-		
411,413,415,					TP401-412	Q5000011	Wrappi	ng terminal C
417,419,420,					11401-412	Q3000011	#rappi	ng terminal C
423,424,428,	1					1		·····
430,431,433,	T I	Ì						
.,		· ·					ļ	<u> </u>
435.440.442.	1				1			
435,440,442,								
443,446,448,								
443,446,448, 451–455,							AF UNIT	
443,446,448, 451–455, 460,465,482,					Symbol No.	Parts No,		Description
443,446,448, 451-455, 460,465,482, 484-486,						Parts No. C0019640	AF unit	Description with components
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493,					Symbol No. PB-1964A	Parts No,	AF unit	Description with components
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497						Parts No. C0019640	AF unit	Description with components
443,446,448, 451–455, 460,465,482, 484–486, 490,491,493, 494,497 C402,403,407,		"		0.047 µF		Parts No. C0019640	AF unit	Description with components
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412,		"	·····	0.047 µF		Parts No. C0019640	AF unit P.C. Bo	Description with components ard
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418,	K13170473	"		0.047 µF	PB-1964A	Parts No. C0019640	AF unit P.C. Bo	Description with components
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427,	K13170473	"	· · · ·	0.047 µF	PB-1964A 	Parts No. C0019640	AF unit P.C. Bo IC, FET	Description with components ard
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438,	K13170473	"		0.047 μF	PB-1964A Q503 Q506	Parts No, C0019640 F0001964A	AF unit P.C. Bo	Description with components ard
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447,	K13170473	"	.,	0.047 µF	PB-1964A Q503 Q506 Q504	Parts No. C0019640 F0001964A G1090077	AF unit P.C. Bo IC, FET	Description with components ard , TRANSISTOR MC3403P (µPC324C)
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462,	K13170473	"	·, ···	0.047 µF	PB-1964A Q503 Q506 Q504 Q502	Parts No. C0019640 F0001964A G1090077 G1090064	AF unit P.C. Bo IC, FET IC	Description with components ard , TRANSISTOR MC3403P (µPC324C) MC14024B
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471,	K13170473	"		0.047 µF	PB-1964A Q503 Q506 Q504 Q502 Q501	Parts No. C0019640 F0001964A G1090077 G1090064 G1090100	AF unit P.C. Bo	Description with components ard , TRANSISTOR MC3403P (µPC324C) MC14024B SN74L\$123N
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495,	K13170473	"		0.047 µF	PB-1964A Q503 Q506 Q504 Q502	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086	AF unit P.C. Bo	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498	K13170473			0.047 μF	PB-1964A Q503 Q506 Q504 Q502 Q501	Parts No. C0019640 F0001964A G1090077 G1090064 G1090064 G1090086 G1090164	AF unit P.C. Bo	Description with components ard , TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449	K13170473 K14179003	"		0.047 μF 0.1 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q505	Parts No. C0019640 F0001964A G1090077 G1090064 G1090086 G1090164 G1090120	AF unit P.C. Bo	Description with components ard , TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407. 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467	K13170473 K14179003 K50177103				PB-1964A Q503 Q506 Q504 Q502 Q501 Q501 Q505 Q514	Parts No. C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G38001900	AF unit P.C. Bo	Description with components ard . TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407. 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2461,467 2478	K13170473 K13170473 K50177103 K50177223	 Mylar SG		0.1 µF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q505 Q514 Q515	Parts No. C0019640 F0001964A G1090077 G1090064 G1090100 G1090164 G1090120 G3800190G G3105641	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " "	Description with components ard . TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467 1478 2409,439,456,	K13170473 K14179003 K50177103			0.1 μF 0.01 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q501 Q505 Q514 Q515 Q511	Parts No. C0019640 F0001964A G1090077 G1090064 G1090100 G1090164 G1090120 G3800190G G3105641 G3303730	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " "	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467 2478 2409,439,456, 466,480,481,	K13170473 K13170473 K50177103 K50177223	 Mylar SG		0.1 µF 0.01 µF 0.022 µF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508	Parts No. C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090120 G3105641 G3303730 G3310000G	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " " "	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2461,467 2461,467 2478 2409,439,456, 466,480,481, 483	K13170473 K13170473 K50177103 K50177223 K50177473			0.1 µF 0.01 µF 0.022 µF	PB-1964A Q503 Q506 Q506 Q504 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G3310000G G3313830	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " " "	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2461,467 1478 2409,439,456, 465,480,481, 483 434	K13170473 K13170473 K50177103 K50177223	Mylar 50		0.1 µF 0.01 µF 0.022 µF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512 Q509,510,513,	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G3310000G G3313830	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " "	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467 2478 2409,439,456, 466,480,481, 483 434 479	K13170473 K13170473 K50177103 K50177223 K50177273 K50177223 K70167224 K70127225	Mylar 50 " Tantalum 35		0.1 μF 0.01 μF 0.022 μF 0.047 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512 Q509,510,513,	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G3310000G G3313830	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " "	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 (402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 349 3451,467 3478 409,439,456, 466,480,481, 483 434 479	K13170473 K13170473 K50177103 K50177223 K50177273 K50177223 K70167224 K70127225	Mylar 50 " Tantalum 35		0.1 μF 0.01 μF 0.022 μF 0.047 μF 0.22 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512 Q509,510,513,	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G3310000G G3313830	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " "	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467 2478 2409,439,456, 466,480,481, 483 434 479	K13170473 K13170473 K50177103 K50177223 K50177273 K50177223 K70167224 K70127225	Mylar 50 " Tantalum 35		0.1 μF 0.01 μF 0.022 μF 0.047 μF 0.22 μF 2.2 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512 Q509,510,513,	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G3310000G G3313830	AF unit P.C. Bo	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407. 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2451,467 2478 2409,439,456, 466,480,481, 483 2434 2479	K13170473 K13170473 K50177103 K50177223 K50177273 K50177223 K70167224 K70127225	Mylar 50 " Tantalum 35		0.1 μF 0.01 μF 0.022 μF 0.047 μF 0.22 μF 2.2 μF 10 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q505 Q514 Q515 Q514 Q515 Q511 Q507, 508 Q512 Q509,510,513, 516	Parts No. C0019640 F0001964A G1090077 G1090064 G1090064 G1090100 G1090086 G1090120 G3105641 G3303730 G3310000C G3313830 G3318150Y	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " " " " " "	Description with components ard TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1815Y
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467 2478 2409,439,456, 466,480,481, 483 434 479	K13170473 K13170473 K50177103 K50177223 K50177223 K50177473 K70167224 K70167224 K70127225 K40120106	Mylar 50 " Tantalum 35		0.1 μF 0.01 μF 0.022 μF 0.047 μF 0.22 μF 2.2 μF 10 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512 Q509,510,513, 516 D510, 511	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G33105641 G3303730 G3310000G G3313830 G3318150Y	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " " " " " "	Description with components ard . TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383 2SC1815Y IN60
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467 2478 2409,439,456, 466,480,481, 483 2434 2479 450,476,496	K13170473 K13170473 K50177103 K50177223 K50177473 K70167224 K70127225 K40120106			0.1 μF 0.01 μF 0.022 μF 0.047 μF 0.22 μF 2.2 μF 10 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512 Q509, 510, 513, 516 D510, 511 D502-506	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G3310000G G3313830 G3318150Y G3318150Y G32090029 G2010070	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " " " " " "	Description with components ard . TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383 2SC1383 2SC1815Y
443,446,448, 451-455, 460,465,482, 484-486, 490,491,493, 494,497 C402,403,407, 408,410,412, 414,416,418, 422,425-427, 429,436-438, 441,444,447, 457,458,462, 463,468-471, 473,474,495, 498 2449 2461,467 2478 2409,439,456, 466,480,481, 483 2434 2479 450,476,496	K13170473 K13170473 K50177103 K50177223 K50177473 K70167224 K70127225 K40120106	Mylar 50 " Tantalum 35 Electrolytic 16 INDUCTOR		0.1 μF 0.01 μF 0.022 μF 0.047 μF 0.22 μF 2.2 μF 10 μF	PB-1964A Q503 Q506 Q504 Q502 Q501 Q502 Q501 Q505 Q514 Q515 Q511 Q507, 508 Q512 Q509, 510, 513, 516 D510, 511 D502-506	Parts No, C0019640 F0001964A G1090077 G1090064 G1090100 G1090086 G1090164 G1090120 G3800190G G3105641 G3303730 G33105641 G3303730 G3310000G G3313830 G3318150Y	AF unit P.C. Bo IC, FET IC " " " " " " " " " " " " " " " " " "	Description with components ard . TRANSISTOR MC3403P (µPC324C) MC14024B SN74LS123N TA7063P µPC2002H NJM78L05 2SK19GR 2SA564A 2SC373 2SC1000GR 2SC1383 2SC1815Y IN60

- 48 --

D501, 518	G2090003	Si 10D1				CAPACITO	R	
				C513	K30176511			510 pF
				C511	K02172050		50 WV	
				C522	K02173100		.,	" 10 pF
				C514	K02179011		**	" 27 pF
	·	CRYSTAL		C546-548	K02175390	**		" 39 pF
X501	H0100260	HC-6/W 3200 kHz #	210026	C510,532,534,	K02175101	"	**	'' 100 pF
X502	H0100421		210042-1	555,566				
X503	H0100422		210042-2	C533	K02175151	"		" 150 pF
X504	H0100423	" 8988.3 kHz #	210042-3	C558, 559	K00179020		,,	SL 240 pF
			_	C512	K06175271		"	
				C504,519-521	K13170103			0.01 µF
			••••	523,531,535,				ŕ
		RESISTOR	.	542545,	5			
R511	J00245560	Carbon film 1/4W VJ	56 Ω	570				
R509,539,557	J00245101		100 Ω	C509,537,574	K13170473			0.047 μF
R533, 546	J00245151		150 Ω	C516	K50177102	Mylar	50 WV	0.001 μF
R503.513.524,			220 Ω	C526	K50177472			0.0047 μF
525				C518,529,530,				0.0047 µF
R512,522,538	J00245471		470 Ω	572				0.01 µr
R504,514,520,			1 kΩ	C525,539-541	K50177223			0.022 µF
523,548,561			1	C528,556,569,				0.022 μF 0.047 μF
R515	J00245222	11 11 11 11	2.2 kΩ	573.574	1.0011473			0.047 µF
R534,535,565	J00245272		2.7 kΩ	C503	K50177104		,,	
R510.562.569.		PT PT PT PT	3.3 kΩ	C507,517,527,		Electrolytic		
578-580				550,551,560,	K4 0170103	Liectrolytic		1 #F
R583	J01245472	" " " тј	4.7 kΩ	567,568,571				
R501,506,531,	1		4.7 kΩ	C557	K40170225		,,	
536,537,542,	1	+,		C561	K40170225			<u>2.2 µF</u>
544,545,549,	1			C536	K40170335			3.3 µF
550,563,566,	1			C\$05,515,538,			25 WV	<u>4.7 µF</u>
575,576,581					K40126106		16 WV	10 µF
R521,527,532	J00245562	17 24 18 81	5.6 kΩ	552,554,564, 565				
	J00245682		5.8 kΩ	C524,553,563	K40126226			
R507,519,529,	J00245103	0 0 0 0	<u>0.8 kΩ</u> 10 kΩ	C508				22 µF
555,556,558,	200240100		TA 194	C508	K40126476 K40126107			47 µF
571, 572	İ			C506				100 µF
R517, 551	J00245153		15 40	C508	K40126227	<i>p</i>		220 µF
R508,518,528,	J00245133	11 42 12 24	15 kΩ 22 kΩ		K40126477			470 µF
540,554,573	100273223		64 K32	C562	K40126336		*	<u> </u>
540,354,375 R559	J00245393		20.60					
R567	J00245393		39 kΩ			TOD04755 -	-	
R516	J00245473		47 kΩ	TC601 606	VALAAAAA	TRIMMER C	·	
R518 R547, 574			56 kΩ	TC501-505	K91000013	ECV-1ZW	20 x 32	20 pF
R547, 574	J00245104	1	00 kΩ					
	J00245154	4	50 kΩ					
R552, 553	J00245224		20 kΩ	1.602	7.1.1.0.0.0.0	INDUCTOR		
R526	J00245274	2	70 kΩ	L502	L1190023	FL-SH 220		22 µH
R564, 577	J00245474		70 kΩ	L501		FL-5H 271		270 µH
	J00245824	8	20 kΩ	L503-506	L1190017	FL-5H 102		1 mH
	J10276229	" composition 1/2W G						
1502	J32276010	Wire wound 1W	1Ω					
		· · · · · · · · · · · · · · · · · · ·						
		· · · · · · · · · · · · · · · · · · ·				TRANSFORM	1ER	
				T501	L0020209	#22	0209	
		POTENTIOMETER						
/R501	J51727101	CR-19R	100 ΩB					
						RELAY		
		·		RL501	M1190002	FBR211A DO	12M	

		MINI CONNECTOR		_ <u>_</u>	CAPACITOR	
0501	P0090043	5048-19A	C607	K30176271	Dipped mica 50WV	270 pF
1502	P0090040	5048-15A	C603	K30176331		330 pF
503	P0090037	5048-08A	C634, 638,	K02175470	Ceramic " CH	47 pF
504	P0090042	5048-05A	642,646	{		
505	P0090041	5048-03A	C626.630	K02175680	11 20 11	68 pF
		,	C623	K02175820	21 (1 E)	82 pF
			C619	K02175101		100 pF
	R0042800	HEAT SINK	C615	K02175151	11 11 11	150 pF
			C611	K02179023	11 11 11 11	180 pF
<u> </u>			C601.602,	K13170103		0.01 µF
	BDEMIY	LOCAL UNIT	604-606,			
Symbol No.	Parts No.	Description	608-610,			
Symbol No.	C0021530	PREMIX LOCAL unit with	612-614,	1	· · ·	
	0.0021530		616-618,	1		
	E00021/62	components P.C. Board	620-622,			
PB-2153	F0002153	r.c. Board	624, 625,			
		· · · · · · · · · · · · · · · · · · ·	627-629,		1	
			631-633.			
		TRANSISTOR	635-637,			
Q601-612	G3303800Y	2SC380TMY	639641,			
		<u> </u>	643-645,			
			647-649			
		DIODE		_ <u>_</u>		
D601-612	G2015550	Si 1S1555				
					CRYSTAL	
			X601	H0100411	HC-18/U 15.9875 MHz	
		RESISTOR	X602	H0101480	17.7075 MHZ	
R605, 610,	J00245101	Carbon film ¼W VJ 100Ω	X603	H0101490	" 21.4875 MHz	
615,620,			X604	H0102294A		
625,628,			X605	H0101500	" 28.4875 MHz	
630, 631,			X606	H0102295A	and the second se	
636, 637,			X607	H0101510	" 35.4875 MHz	
641, 642,			X608	H0102296A	" 38.9875 MHz	
646, 647,			X609	H0101520	" 42.4875 MHz	
651, 652,			X610	H0101530	" 42.9875 MHz	
656,657			X611	H0101540	" 43.4875 MHz	
R632	J00245151	" " " 150 Ω	X612	H0101550	" 43.9875 MHz	
R605, 608,	J00245561	<u>, , , , , , , , , , , , , , , , , , , </u>				
613, 618,						
623		· · ·			TRANSFORMER	
R604, 609,	100245102	" " " 1 kΩ	T601-612	L0020017		
614, 619,						
614, 619, 624, 6 2 9,					INDUCTOR	
			L601	L1190016	FL5H-101K	Hµ 100
633, 638,			2001			
643,648,				SELE	CT SWITCH UNIT	
653,658	100246222	<u></u>	Cumbert Mar	- T	Description	
R661-663	J00245222	2.2 80	Symbol No.	Parts No.	SELECT SW unit with c	
R602, 607,	J00245333	33 846	PD 10((7	C0019660	· · · · · · · · · · · · · · · · · · ·	
612, 617,			PB-1966C	F0001966C		
622, 627,		1			0:005	
634, 639,				Captone		
644, 649,			D701	G2090001	Si 10D1	
654,659						
R601.606.	100245563	<u>, , , , , , , , , , , , , , , , , , , </u>	L	-+	RELAY	
611, 616,	1		RL701	M1190002	FBR211A D012M	
621, 626,						
635, 640,	i					
645,650,		1		-	SWITCH	
655,660			· \$701	M4090006	6B0003CC2060	

•

۰.

					TRIMMER CAPACITOR
J 701	P0090049	5048-16A	TC801	K9000001	TSN-100D15 15
			TC802	K91000016	ECV-1ZW 50 x 32 50
·····					
	1				INDUCTOR
		VFO UNIT	L801	L0020268	#220268
Symbol No.	Parts No.	Description	L804, 805	L1190007	Micro inductor FL-4H 1.8 µ
	C0014400	VFO assembly 3420	L803, 806	L1190001	250 μ
		PCB with components	L802	L1190040	" " S4 102K 1 m
PB-1440B	F0001440B	P.C. Board			•
· 		· · · · · ·			
					RECEPTACLE
		FET & TRANSISTOR	J801	P1090012	\$I-63 03-1
Q802	G3800190C				
Q801, 803	G3303720Y	Transistor 2SC372Y			
·					77 844444
	· · · · ·	<u></u>	_	OFODODA	TERMINAL
	<u>.</u>	21005		Q5000005	Lighthouse type
D801	G2022360	DIODE Varactor 1\$2236		Q5000011	Wrapping terminal C
1001	02022300	Varactor 152250	···	- <u> </u>	
		···			
	<u>† </u>	· ·····			· · · · · · · · · · · · · · · · · · ·
	+	RESISTOR			
R809, 811	J00245101	Carbon film 1/4W VJ 100 Ω		BE	CT. B UNIT
R8 07	J00245221	" " " " 220 Ω	Symbol No.	Parts No.	Description
R805, 808	J00245222	" " " 2.2 kΩ		C0019670	RECT. A unit with components
R802	J00245332	"""""3.3 kΩ	PB-1967	F0001967	P.C. Board
R801	J00245103	" " " 10 kΩ			
R803	J00245183	"""""" 18 kΩ			· · · · · · · · · · · · · · · · · · ·
R80 4	J00245223				
R806, 810	J00245104	" " " 100 kΩ			IC, TRANSISTOR
			Q901	G1090162	IC μPC78L12
			Q903	G3104950O	TR 2SA495(O)
0003	W00150000	CAPACITOR			
C807	K02173080 K06173080	Ceramic disc 50WV CH 8 pF			0.005
C801 C803	K06175080	"""UJ 8 pF """ 12 pF			
C803	K02175180	" " " CH 18 pF	D907 D901-904	G2090001	Si 10D1
C805, 814	K02179013	" " " 33 pF	D901-904	G2090002 G2090003	" 10D10 " V06B
C808, 814	K02175390	33 pr """ " 39 pF	D905, 906		
C808, 818	K02179023	39 pF """ 180 pF	D708	G2090007	Zener WZ061
C821, 823	K00175471	" " " 470 pF			
C809,810,812,	K13170103				
815,819,820,	A15170103	″″″″ 0.01 μF		-	RESISTOR
815,819,820, 824,826			R908	J01245560	Carbon film 1/4W TJ 56 Ω
	K 20176411	Dipped mica " 430 pF	R905	J10276220	- composition 1/2W GK 22
	K30176431 K30209001	Dipped mica " 430 pF " " 1000 pF	R901-904	J10276220	·····································
C825	K70167334		R907	J20339001	Metallic film 2W 0.4 Ω
		22παιαπ 10 V V 0.33 μP		120339001	wetanciani 2w 0.4 12
		· · · · · · · · · · · · · · · · · · ·			
		VARIABLE CAPACITOR			CAPACITOR
VC801	K90000024	C521 R112	C901-905	K13170103	Ceramic 50WV 0.01 µI
			C908911	K40140106	Electrolytic 25WV 10 µI
		· · · · · · · · · · · · · · · · · · ·	C907	K40140107	" " 100 µF

C906	K41140338	Electrolytic 25WV 3300 µF			CAPACITOR
	[·	C1017	K13170473	
			C1016	K12279003	" 500WV 0.0022 μF
			C1005, 1006,	K12279004	″ 0.0047 μF
		RELAY	1013-1015,		
RL901	M1190003	FRL-264 D012/04CS-01	1018		
			C1010	K12279002	
	· ·		C1009	K40240106	Electrolytic 250WV 10 µF
· · · ·	Q5000011	Wrapping terminal C	C1011	K40240336	" " 33 μF
	Q5000004	Test point D	C1012	K40240476	″″″ [″] 47μF
	1	1 · · · · · · · · · · · · · · · · · · ·	C1001-1004	K40270106	" 450WV 10 μF
			C1007, 1008	K40260226	" 350WV 22 μF
	· · ·				· · · · · · · · · · · · · · · · · · ·
	RE	CT. B UNIT			
Symbol No.	Parts No.	Description			i
	C0019680	RECT. B unit with components	· · · · ·	Q\$000011	Wrapping terminal C
PB-1968B	F0001968B		- <u>†</u> ·		· · · · · · · · · · · · · · · · · · ·
······ · · · · · · · · · · · · · · · ·	1			1	<u></u>
	<u> </u>	······	···•••	+	
	†				· · · · · · · · · · · · · · · · · · ·
		TRANSISTOR		+	· · · · · · · · · · · · · · · · · · ·
Q1003	G3106390	2SA639		CADA	CITOR UNIT
Q1003 Q1001	G3107330	23A033 2SA733	Symbol No.	Parts No.	Description
Q1002	G3303720Y		0711001110.	C0019690	CAPACITOR unit with component
~****	000007201	2000/22	PB-1969A	F0001969A	
	<u> </u>		10-1909A	10001303A	F.C. Board
		· · · · · · · · · · · · · · · · · · ·			
		DIQDE			
D1004 1005	0001000				· · · · · · · · · · · · · · · · · · ·
D1004, 1005,	G2015550	Si 1\$1555			RESISTOR
1008-1011	<u>.</u>		R1101, 1102	J10276474	Carbon composition 1/2W GK 470k
D1002, 1003,	G2090002	" 10D10		ļ	
1012	<u> </u>	·····			
D1006, 1007	G2090001	" 10D1			· · · · · · · · · · · · · · · · · · ·
D1001	G2090081	" SM1-12			CAPACITOR
		· · · · · · · · · · · · · · · · · · ·	C1101, 1102	K43270003	Electrolytic 500WV 200 µF
		· · · · · · · · · · · · · · · · · · ·			(CE-62LW)
		RESISTOR			
R1021	J00245681	Carbon film 1/4W VJ 680 Ω			
R1011, 1016,	300245472	" " " " 4.7 kΩ			
1020					· ·
R1013, 1015	J00245103	"""""10 kΩ		TRIM	MER A UNIT
R1014	J00245123	""" 12 kΩ	Symbol No.	Parts No.	Description
R1017-1019	J00245223	""""" 22 kΩ		C0019700	TRIMMER A unit with components
R1012	J00245563	"""" 56 kΩ	PB-1970		P.C. Board
R1010	J20306562	Metallic film 1W 5.6 kΩ	1	····•	
R1022	J 20306390	" " 39 Ω	1		
R1005	J20336391	" " 2W 390 Ω	1	· · · · · · · · · · · · · · · · · · ·	
R1006	J20336471		1		CAPACITOR
R1008	J20336222	<u></u>	C1203	K30176271	Dipped mica 50WV 270 pF
R1007	J20336332	" " 3.3 kΩ	C1203	K30176391	270 pF
	J20336473	<u> </u>	C1208	K30176651	390 pr """ 650 pF
		47 K42	C1202		630 pr
R1009		Carbon composition 3/W GK 470 kn		K30209001	1000 pr
R1009			C1201	K30209003	1500 pr
R1009			1		
R1009			C1206	K02173100	
R1009 R1023		POTENTIOMETER	C1205	K02179012	" " " 30 pF
R1009		ΡΟΤΕΝΤΙΟΜΕΤΕR V18K3-2 10 kΩB			
R1009 R1023			C1205	K02179012	" " " 30 pF

	T	TRIMMER CAPACITOR	C1407	K30276391	Dipped mica 500WV 390 pF
TC1203	K91000032		C1402	K30276651	" " " 650 pF
TC1202	K91000052		C1401	K30279055	
TC1201	K91000033				
TC1206	K91000013	· · · · · · · · · · · · · · · · · · ·		1	
TC1204, 1205	K91000016	" 50 x 32 50 pF	• • •	<u> </u>	· · · · · · · · · · · · · · · · · · ·
					TRIMMER CAPACITOR
	<u> </u>		TC1404, 1405	K91000031	
			TC1402, 1403	K91000032	
		INDUCTOR	TC1401	K91000033	· · · · · · · · · · · · · · · · · · ·
L1201	L0020545	Trap coil #220545	101401		
L1201	120020343	Trap con #220045		<u> </u>	
· ·	+			+	
	+				1
		· · · · · · · · · · · · · · · · · · ·		-	· · · · · · · · · · · · · · · · · · ·
				DANES MAL	DTH CONTROL UNIT
	TOIM		Symbol No.	Parts No.	Description
Symbol No.	Parts No.	ER B BOARD Description	Gymporino,	C0019720	B.W. CONT. unit with components
	C0019701	TRIMMER B unit with components	PB-1972	F00019720	P.C. Board
PB-1970	F0001970	P.C. Board	1.0-1774	10001772	L.C. Duald
· 0-17/U	1.0001370			<u> </u>	ļ
					1
·····,				<u> </u>	LED
		CAPACITOR	D1501	G2090060	GD4-203 \$RD
C1303	K30176221	Dipped mica 50WV 220 pF		02090000	GD4-205 SRD
C1305	K30176221	" " " 390 pF			
C1306	<u></u>	390 pr		ļ <u>-</u>	······
	K30176621	620 pr			
C1301	K30209003	1300 pF		100046160	RESISTOR
	K02173080	Ceramic 50WV CH 8 pF	R1501	J00245152	Carbon film 1/4W VJ 1.5 kΩ
C1304	K02175680	" " 68 pF			<u></u>
	· · ·				· · · ·
			VD1C01	160710600	POTENTIOMETER
		TRIMMER CAPACITOR	VR1501	J50710502	V10K8-1-2 5 k ΩB
TC1303	K91000032				
TC1302	K91000052				
TC1301	K91000033			 	
TC1306	K91000012	ECV-1ZW 10 x 32 10 pF			SWITCH
TC1304, 1305	K91000016	" 50 x 32 50 pF	\$1501	N4090008	1B0001AC2060
		· · · · · · · · · · · · · · · · · · ·		<u> </u>	· · · · · · · · · · · · · · · · · · ·
		· · · · · · · · · · · · · · · · · · ·	- -		
			-		
c					ER BOARD
		· · · ·	Symbol No.	Parts No.	Description
				C0017140	Driver board with components
					(without vacuum tube)
			PB-1714A	F0001714A	P.C. Board
		ER C BOARD			
Symbol No.	Parts No.	Description			
	C0010920	TRIMMER C unit with components			
PB-1092	F1001092	P.C. Board			
		······	V1601	G6090002	12BY7A
		CAPACITOR			
		Dipped mica 500WV 10 pF			VACUUM TUBE SOCKET
1405	K30276820	"""" 82 pF	VS1601	P3090022	SB-9403
		" " " ODD - E			

		RESISTOR			CAPACITOR
R1605	J10276470		C1703	K12279001	Ceramic disc 500WV 0.001 µF
R1602, 1604	J10276560	" " " 56 Ω	C1704, 1710	K12279002	
R1603	J10276101	" " " 100 Ω	C1705-1709,	K13170473	" " 50WV 0.047 µF
R1601	J10276473	" " " " 47 kΩ	1711, 1712		1
	1		C1701	K31306102	Moulded mica 1kWV 1000 pF
	1		C1702		Dipped mice 500WV 5 pF
	1	······································			Server and a sound She
	<u>†</u>	CAPACITOR		+	
C1601, 1602	K12279002				
C1601, 1602	K12279002				
1606	17131104/3	ου το οι	1 1 201	11100000	INDUCTOR
C1605	120020041		L1701	L1190020	Micro inductor 150 µH
01003	K30279051	Dipped mica 500WV 1000 pF	L1704	L1190039	лц 00c
			L1702, 1703	L1020307	RF choke #220307
	<u> </u>		(R1701,1702)		
	<u> </u>				
		INDUCTOR			
L1601	L1190020	Micro inductor FL5H 150 µH			
L1602(R1602)	L1020029	#220029		Q5000011	Wrapping terminal C
				1	
	Q5000011	Wrapping terminal C	1	1	
		·····	1	1	
	1				CONTROL UNIT
	····-		Symbol No.	Parts No.	Description
	<u> </u>			C0019730	CLAR.CONT.unit with component
	l		PR-10727		
		AL BOARD	PB-1973B	F0001973B	P.C. Board
Cu				łl	
Symbol No.	Parts No.	Description		<u></u> ∔ · ⊣	
	C0017151	Final board with components	 	ļ	
		(without vacuum tube)	_	<u> </u>	DIODE
PB-1715B	F0001715B	P.C. Board	D1801	G2090001	Si 10D1
		· · · · · · · · · · · · · · · · · · ·	D1802	G2090060	LED GD4-203SRD
			l		
		VACUUM TUBE			
V1701, 1702	G6090001	6146B			RESISTOR
			R1803	J00245102	Carbon film 1/4W VJ 1 kΩ
		-	R1804, 1805	J00245152	" " " " 1.5 kΩ
			R1802	J00245332	" " " <u>3.3 kΩ</u>
		VACUUM TUBE SOCKET	R1801	J00245472	" " " 4.7 kΩ
VS1701, 1702	P3090024	\$B-3606			
			t	<u> </u>	
		• · · · · · · · · · · · · · · · · · · ·	f		······
			 		POTENTIONETER
- · · · · · · · · · · · · · · · · · · ·		DIODE	VR1801		POTENTIOMETER
D1701			471001	J50710501	V10K8-1-2 500 ΩB
AT101	02090002	Si 10D10	łi	· · · · · · · · · · · · · · · · · · ·	
		•	ļ		
				I	
					CAPACITOR
		RESISTOR	C1801-1803	K13170473	Ceramic 50WV 0.047 µF
R1701, 1702	J10276560	Carbon composition 1/2W GK 56 Ω			
L1702, 1703)					
R1703, 1704,	J10276101	<i>" "</i> 100 Ω			· · · · · · · · · · · · · · · · · · ·
1705					RELAY
	J31333010	Meter shunt 2W 1 Ω	RL1801		FBR211A D012M
				1	· MORTHY PAIGH
	i				

- 54 -

		SWITCH			PLUG					
SW1801	N4090011	2B0005FC206	P2201	P1090073	5047-06 (with wire T9202430)					
	· · · · · · · · · · · · · · · · · · ·	·	P2202	P1090075	5047-08 (" T9202440A)					
	_				· · · · · · · · · · · · · · · · · · ·					
				co	UNTER UNIT (3420)					
		D BOARD	Symbol No.	Parts No.	Description					
Symbol No.	Parts No.	Description	PB-2086A	F0002086A						
PB-1974A	C0019740	LED board with components P.C. Board		C0020862	P.C.B. with components					
10-17/4K	100019742	r.c. board			······································					
		. . .	1		IC, FET & TRANSISTOR					
- 	1		Q2312	G1090249	IC MSM9520RS					
	1	LED	Q2320	G1090079	µPA54H					
D1901-1906	G2090060	GD4-203SRD	Q2305	G1090299	РС7805Н					
· · · · · · · · · · · · · · · · · · ·			Q2301	G4800730	FET 3SK73					
	<u>.</u>		Q2321	G3104960Y	••••••••••••••••••••••••••••••••••••••					
	 		Q2306-2311,	G3109520L	" 2SA952L					
R1901, 1902	J01245102	RESISTOR Carbon film 1/4W TJ 1 kΩ	2313-2319 Q2303	G3316740L	" 2SC1674L					
	301240102	Carbon film 1/4W TJ 1 kn	Q2303	G3318740L G3318150G	23C1074E					
	<u>†</u>			000101000	20010100K					
			1		· · · ·····					
					DIODE					
			D2301-2313	G2015550	Si 1S1555					
	1	R SWITCH BOARD								
Symbol No.	Parts No.	Description								
PB-1975A	C0019750	LEVER SW board with components P.C. Board	N2201	110100000	CRYSTAL					
10-13/3A	F0001973A	r.c. Board	X2301	H0102272	HC-18/U 6.5536 MH2					
· · · ·		· · · · · · · · · · · · · · · · · · ·		<u> </u>	· · · · · · · · · · · · · · · · · · ·					
			-	<u>† </u>	RESISTOR					
		RESISTOR	R2312	J00245100	Carbon film ¼W VJ 10Ω					
R2006	J01245560	Carbon film 1/4W TJ 56 Ω	R2331, 2334,	J00245330						
R 2005	J01245101	″ ″ ″ ″ 100 Ω	2337, 2340,	j l						
R2001	J01245121	" " " 120 Ω	2343, 2346,							
R2002	J01245391	" " " 390 Ω	2349							
R2008	J00245562	<u>" " VJ 5.6 kΩ</u> " " TI 68 kΩ	R2350	J00245560	<u> </u>					
R2004	J01245683	<u>" " ΤJ 68 kΩ</u>	R2308, 2318, 2320, 2322,	J00245101	΄΄΄΄΄΄΄΄ 100 Ω					
			2320, 2322,							
			2324, 2320,							
		SWITCH	R2301	J01245221	·····································					
52001-2004	N3090002	SLE62301	R2307, 2311,	J00245221	" " VJ 220 Ω					
\$2005	N3090008	SLE64251	2312							
			R2352	J00245331	" " " " 330 Ω					
			R2351	J00245471						
			R2317, 2319,	J01245102	"""TJ 1 kΩ					
·			2321, 2323,	ł						
		SPLAY UNIT (3420)	2325, 2327,							
Symbol No.	Parts No.	Description	2330, 2333, 2336, 2339,							
B-2098A		Printed Circuit Board	2330, 2339, 2345, 2345, 2345, 2342, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2345, 2355, 2345, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 23555, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 2355, 23555, 2355, 23555, 23555, 23555, 23555, 23555, 23555, 235555, 235555, 23555, 2355555, 235555, 23555, 235555555, 235555, 235555555555							
	C0020982	P.C.B. with components	2348							
			R2329, 2332,	J00245152	" " VJ 1.5 kΩ					
			2335, 2338,							
			2341, 2344,							
		DISPLAY LED	2347							
2201-2206	G2090069	HP5082-7623	R2302, 2315	J00245562	" " 5.6 kΩ					

ě.

R2313	J00245103	Carbon film	14W 1	7J	10 kΩ			
R2304, 2309	J01245473	" "			47 kΩ		··· · ·	
R2314	J01245104	11 82	-		100 kΩ	<u> </u>	-	
R2316	J00245104	11 11	·· · ·	73	100 kΩ			
	700245104	1			100 834			
C2324	K03170000	CAPACITOR			1 0 1 5			
C2324 C2325	K02179008		50WV C		20 pF 47 pF			<u> </u>
C2320	K02175101				47 pF 100 pF		<u> </u>	······································
C2301, 2304	K13170102		50WV C		0.001 µF			
C2302, 2305,	K13170103				0.001 µF			
2308, 2309,					0.01			
2311, 2312,	-					······	·	
2314, 2315,						}		
2317, 2319,		ļ						
2321, 2323,						•		
2326-2330								· · · · · · · · · · · · · · · · · · ·
C2323	K50177103	Mylar			F بر 0.01		· · · · · · · · · · · · · · · · · · ·	
C2322	K71137685		20WV		<u>6.8 µ</u> F			
C2310, 2318	A	Electrolytic			10 µF		· · · · · ·	
C2313	K40109011		10WV		33 µF			
C2316	K40129001		16WV		 330 μF			IVERTER (OPTION)
						Symbol No.	Parts No.	Description
								TRANSISTOR
						Q3201, 3202	G3090002	T20A6 with insulator
		TRIMMER CA	PACIT	ÖR			1	
TC2301	K91000030	ECV-1ZW 40			40 pF	-	1	RESISTOR
*			· · · ·			R3202	J31306339	
						R3201	J20376221	
		INDUCTOR						
L2301	L2030068							
						1	<u> </u>	CAPACITOR
						C3202	K52247474	Metallized paper 250WV 0.047 µF
		CONNECTOR				C3201		Electrolytic 25WV 220 µF
J2301	P0090051	5048-06A				····		
J2302	P0090054	5048-07A					· † · · · · · · · · · · · · · · · · · ·	
J2303	P0090037	5048-08A		-				CONNECTOR
P2301, 2302	P0090045	SQ4052				P3201	P0090066	AC9M
P2303	P1090186	3021-03 (with	wire T9	201	380A)			
							T9012720	DC POWER CORD
							Q0000009	FUSE 20 A
						I		
		······································		.·.				
				.:. 				CESSORIES
				···		Symbol No.		Description
		······································		··· ···		Symbol No.	ACC Parts No.	Description AC POWER CORD
		· · · · · · · · · · · · · · · · · · ·		····		Symbol No.	ACC Parts No. T9012380A	Description AC POWER CORD 2 wire, 2 prong plug
		· · · · · · · · · · · · · · · · · · ·				Symbol No.	ACI Parts No. T9012380A T9012481A	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug
				····		Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug 3 wire, 3 prong plug (UL)
				····		Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A T9012484	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug 3 wire, 3 prong plug (UL) 3 wire, 3 prong Australian plug
				····		Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A T9012484 T9012683A	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug 3 wire, 3 prong plug (UL) 3 wire, 3 prong Australian plug 3 wire, 2 prong EU plug
				····		Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A T9012484 T9012683A P0090065	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug 3 wire, 3 prong plug (UL) 3 wire, 3 prong Australian plug
				····		Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A T9012484 T9012683A P0090065 P0090018	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug 3 wire, 3 prong plug (UL) 3 wire, 3 prong Australian plug 3 wire, 2 prong EU plug
						Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A T9012582A T9012683A P0090065	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug 3 wire, 3 prong plug (UL) 3 wire, 3 prong Australian plug 3 wire, 2 prong EU plug CONNECTOR PLUG QS-P6FL
						Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A T9012484 T9012683A P0090065 P0090018 P0090035	Description AC POWER CORD 2 wire, 2 prong plug 3 wire without plug 3 wire, 3 prong plug (UL) 3 wire, 3 prong Australian plug 3 wire, 2 prong EU plug CONNECTOR PLUG QS-P6FL PIN PLUG STP58 ACC PLUG PA602B04 FUSE (100V-117V) SA
						Symbol No.	ACC Parts No. T9012380A T9012481A T9012582A T9012484 T9012683A P0090065 P0090018 P0090035	Description AC POWER CORD 2 wire, 2 prong plug 3 wire, 2 prong plug 3 wire, 3 prong plug (UL) 3 wire, 3 prong Australian plug 3 wire, 2 prong EU plug CONNECTOR PLUG QS-P6FL PIN PLUG STP58 ACC PLUG PA602B04

- 56 -

		AMUNIT'						CAPACITO	3		
Symbol No.	Parts No.	C	escrip	tion		C2420	K30176331	Dipped mica	50 WV		39 0 pF
	C0020400	AM unit with c	ompoi	nents		C2416	K02175390	Ceramic		СН	39 pF
PB-2040	F0002040	P.C. Board				C2417, 2426	K02175101	tr.	**		100 pF
						C2418	K02175151	47	11	**	150 pF
		FET & TRANS	ISTOP	3		C2401	K02175221	"			220 pF
Q2404	G3800190G		19GR			C2419, 2421-	K13170103		0	••	0.01 µF
Q2406	G4800510C		51-03			2423, 2428,					
Q2405,2406,	G3303800Y	TR 2SC	80TM	-Y		2429, 2434,					
2407						2436, 2437-					
Q2401	G3307320G		32TM	-GR		2440, 2445-					
Q2402, 2409	G3318150Y	" 2SC1	815Y		<u>_</u> _	2447 2449					
	· · ·					C2425, 2427,	K13170473		**		0.047 μF
	L	DIODE				2430-2433,	Į				
D2406	G2090029	Ge. 1N60				2436, 2439		. ·			
D2401, 2402,	G2015550	Si. 1815	55			C2451	K50177102	Mylar			0.001 µF
2404, 2405						C2407	K50177222	"			0.0022 µF
	<u> </u>					C2410, 2415,	K50177103	t)	**		Fµ 0.01
	110100400	CRYSTAL	0000			2435, 2438,					
X2401	H0100423	HC-18/U	8988	3.3 kH	z	2447, 2449					0.045 -
						C2402	K50177473				0.047 µF
	100345455	RESISTOR	1/37	VJ	47.0	C2414	K50177224				0.22 µF
R2441, 2457	J00245470	Carbon film	<u>44W</u>	<u>vj</u>	<u>47 Ω</u> 56 Ω	C2405, 2450,	K40170105	Electrolytic			1 μF
R2455	J00245560				<u>56 Ω</u> 100 Ω	2453	¥40140476		76 11/17		A
R2411, 2414, 2418, 2422,	J00245101				100 12	C2452 C2406, 2408,	K40140475 K40126106		25 WV 16 WV		4.7 μF
2418, 2422, 2425, 2432,						2409, 2424,	K40120100		10 44 1		10 µF
2423, 2432, 2434, 2447						2409, 2424, 2454					
R2406, 2423	J00245331	47 17			330 Ω	C2446	K40126476	"			47 µF
R2445, 2452	J00245471				470 Ω	C2403	K40126107	"	~		100 μF
R2409, 2419,	J00245102	++ -++		.,	1 kΩ	C2413	K40126227		·····		۲۵۵ µF
2435, 2436,					•						
2438-2440										OR	
	1					TC2402	K91000012	ECV 1ZW	10 x 32		10 pF
R2437	J01245102		·	TJ	1 kΩ	TC2401	K91000013	11	20 x 32		20 pF
R2431	J00245272	,, ,,		VJ	2.7 kΩ		· · · ·				•
R2401, 2410,	J00245332	" "	11	.,	3.3 kΩ			INDUCTOR			·····
2453, 2456						L2401, 2403	L1190016	FLSH-101K			Hµ 100
R2454	J01245332		••	TJ	3.3 kΩ	L2402	L1190017	FL5H-102K			1 mH
R2404	J00245392			VJ	3.9 kΩ	f .					
R2420,2429	J00245472	H H	••	**	4.7 kΩ	[TRANSFOR	MER		
R2442, 2444	J00245562	11 11			5.6 kΩ	T2401	L0020141	R12-4171			
R2402, 2424,	J00245103	10 11	11		10 kΩ						
446,2449,2458						· · · · · · · · · · · · · · · · · · ·		CONNECTO	R		
R2407	J00245123				12 kΩ	J2401, 2404	P1090016		SQ3056		
R2405, 2433	J00245153	PR 71			15 kΩ	J2402	P0090041		5048-03	A	
R2430	J00245183	11 11	**	**	18 kΩ	J2403	P0090037		5048-08	A	
R2443, 2450	J00245223	** **	"	.,	22 kΩ	P2401	P0090075		P-7015		
R2403	J00245273			"	_27 kΩ						
R2408, 2412,	J00245333	n n	"		33 kΩ		Q5000011	Wrapping ten			
2421							B4025945B	P.C.B. suppor	rt D		
R2416	J00245393	1e ei	1.5	,,	39 kΩ						
	J00245563			•1	56 kΩ						
	J00245683	41 42	"	"	68 kΩ						
· · ·	J00245104		••	,,	100 kΩ						
2451											
		THERMISTOR						···· · ·			
H2401	G9090003		D33A								

- 57 -



